

Design of DTC-Assisted High Performance Fractional-N PLLs

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Outline

- **Fractional-N PLL Design Challenges**
- **PLL Architecture Review**
- **DTC-Assisted Phase Detector Design**
- **Digital Calibrations to Enhance PLL Performance**
- **LO Chain Design Example for 5G NR**

Demand for Low Jitter Fractional-N PLLs

Latest wireless standards strive for very high throughput

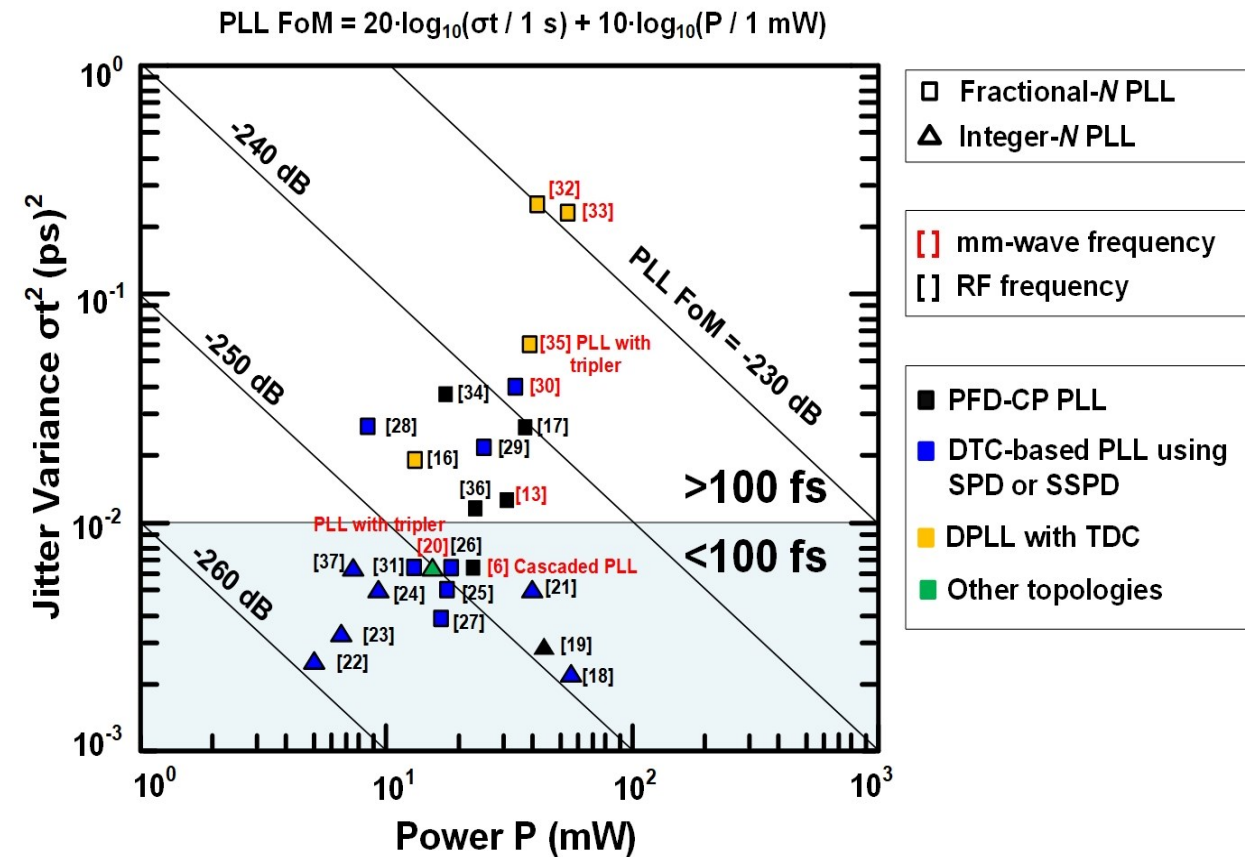
- WiFi 7 enables 4k-QAM at 7GHz
- Cellular FR2 (MMW) transceivers to support 256-QAM at 40+ GHz

→ RMS jitter <100fs is required for LO

DSB IPN Requirement (dBc)		Integrated RMS jitter (fs) (Int. 1kHz to 100MHz)				
		29.5GHz	40GHz	43GHz	47GHz	7.125GHz
64-QAM	-30	171	126	117	107	707
256-QAM	-33	121	89	83	76	500
1K-QAM	-44	NA	NA	NA	NA	141
4K-QAM	-47	NA	NA	NA	NA	99.8

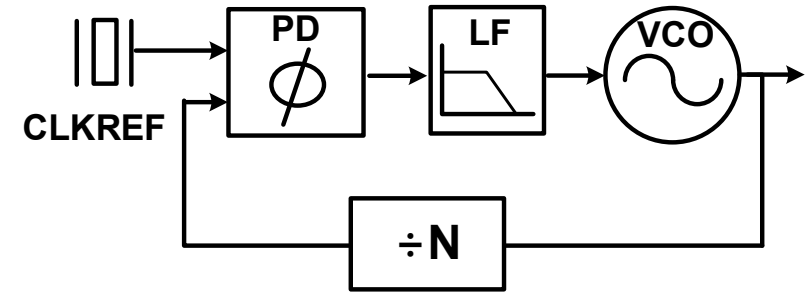
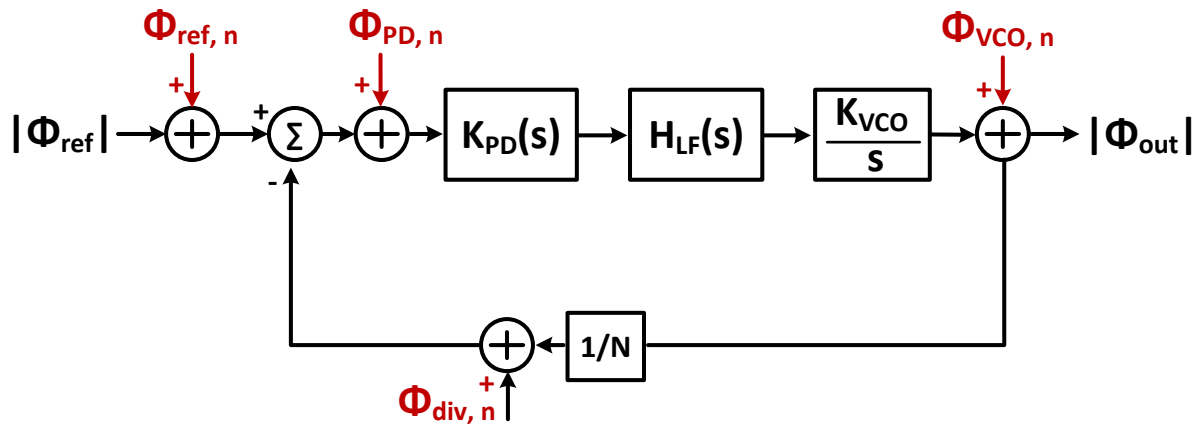
State-of-the-Art Low Jitter Fractional-N PLLs

- A few frac. N PLLs achieved $<100\text{fs}_{\text{rms}}$ jitter; FoM is still worse than integer-N PLLs
- Even harder for mmW PLLs due to mmW VCO
- Analog/digital PLLs using DTC-assisted PD achieves lower jitter and better FoM

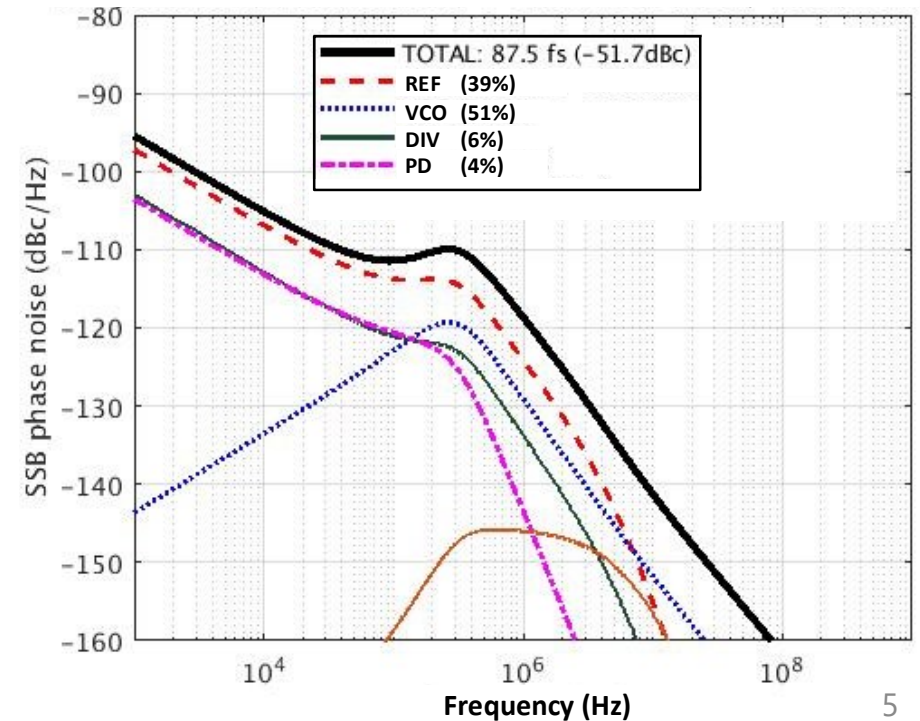


Major Noise Source in Any PLLs

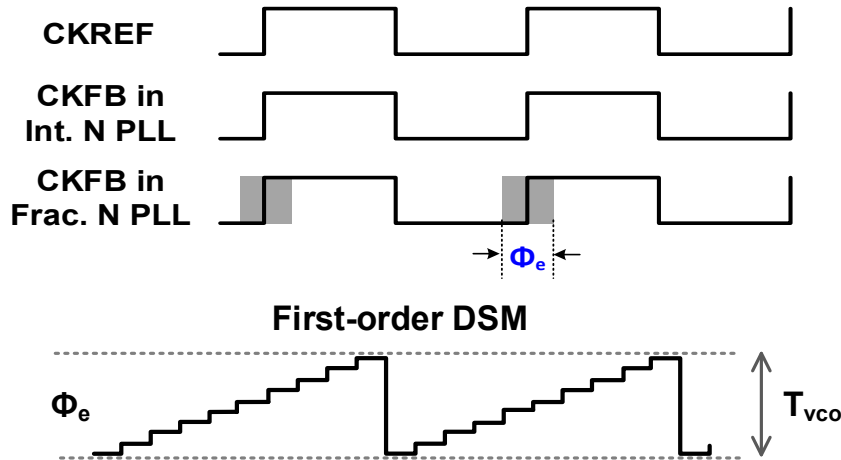
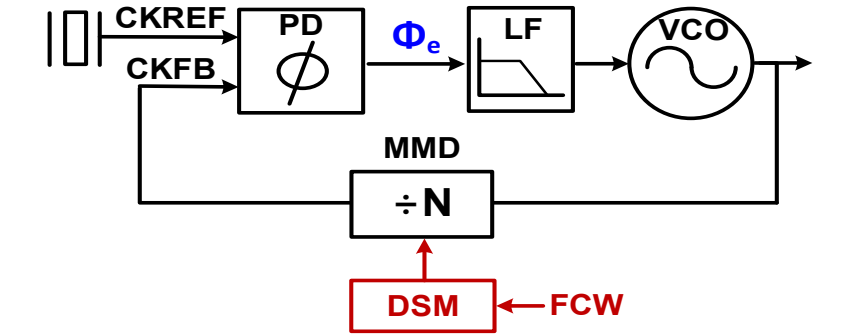
- Major noise source in a PLL
 - VCO/DCO → Dominate
 - CLKREF
 - Phase detector (PD) → try to minimize
 - Feedback divider → negligible



SSB PN contributors at a low jitter 6-GHz PLL output

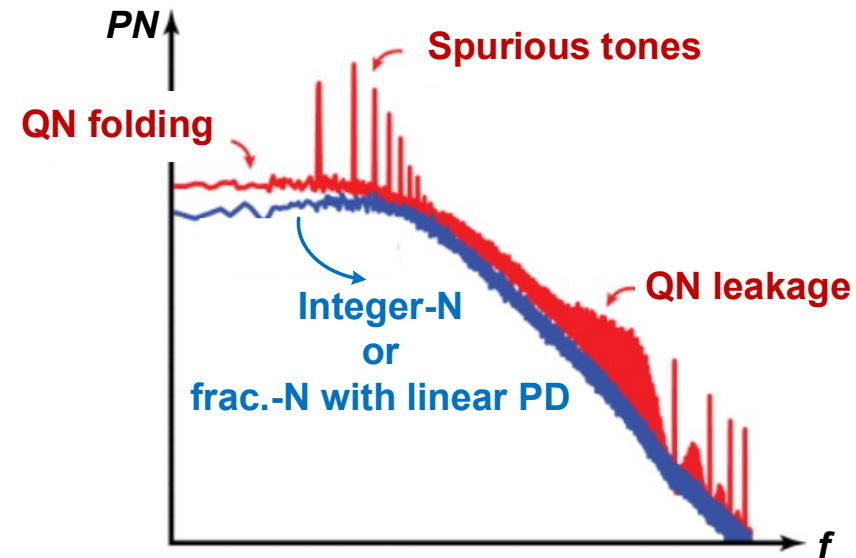


Extra Challenges in Fractional-N PLLs



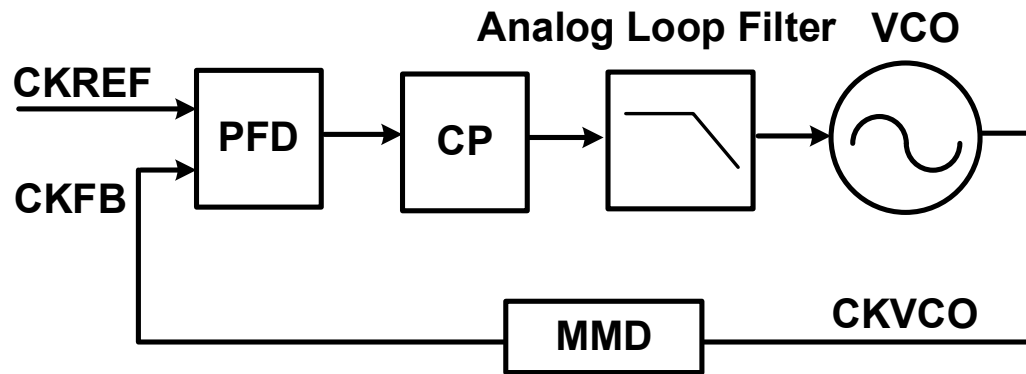
- Mash1:** $-T_{VCO}/2 \leq \Phi_e \leq +T_{VCO}/2$
- Mash1-1:** $-T_{VCO} \leq \Phi_e \leq +T_{VCO}$
- Mash1-1-1:** $-2T_{VCO} \leq \Phi_e \leq +2T_{VCO}$

- **DSM QN**
- **Much wider dynamic range (DR) needed in PD**
- **Fractional spurs:**
 - **MMD, PD nonlinearity → result in noise folding, higher inband noise**
 - **Coupling between VCO/DCO and PD/CLKREF**

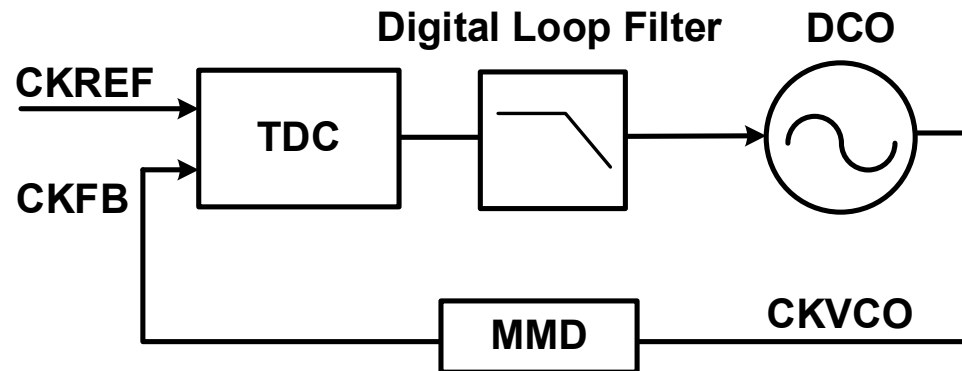


Major PLL Topologies – PD is Key Difference

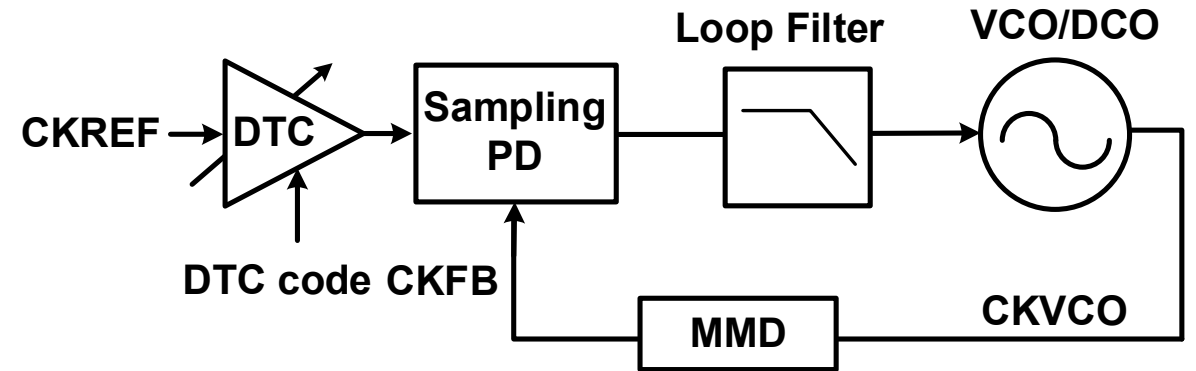
■ Analog PLL using PFD-CP



■ DPLL using TDC: small LF size, flexible calibration and configurability



■ PLL using DTC-assisted PD



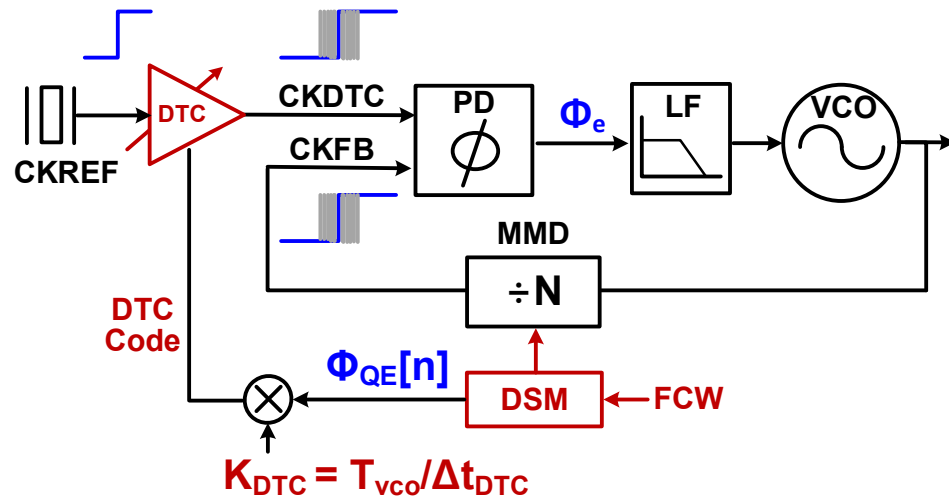
Show more advantages, gain popularity in both academia and industry

PD	▪ Thermal/flicker noise, maybe QN
design	▪ Linearity over required DR
metrics	▪ P_{dc}
	▪ Complexity, area

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- Fractional-N PLL Design Challenges
- **PLL Architecture Review**
- DTC-Assisted Phase Detector Design
- Digital Calibrations to Enhance PLL Performance
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Advantages of DTC-assisted PD

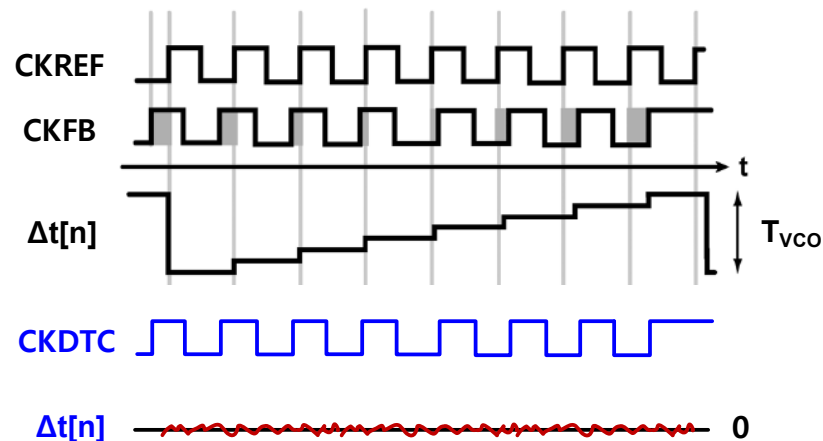


- DTC is a Digital-to-Time Converter
- DTC cancels accumulated QE on CKFB due to DSM

→ Near zero phase error at PD after locking

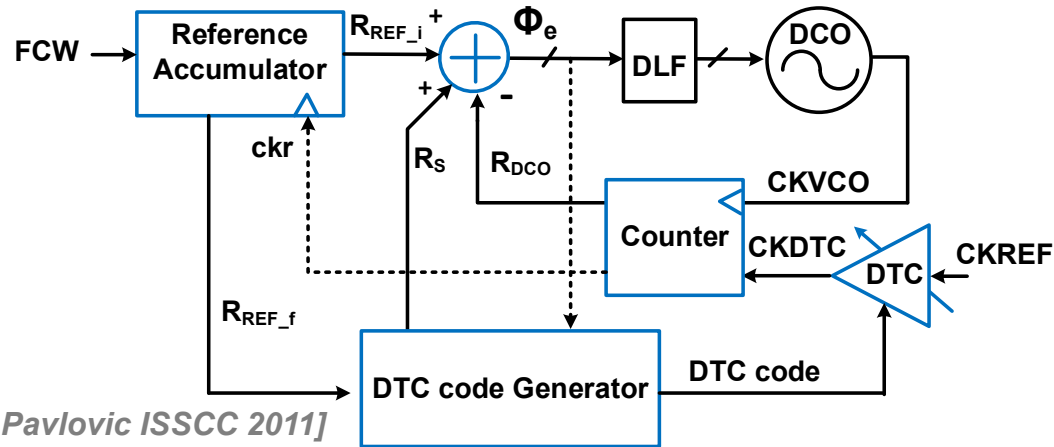
Just like integer-N case!

→ Can use high gain PD of small dynamic range for lower inband noise, high linearity, lower P_{dc} ...



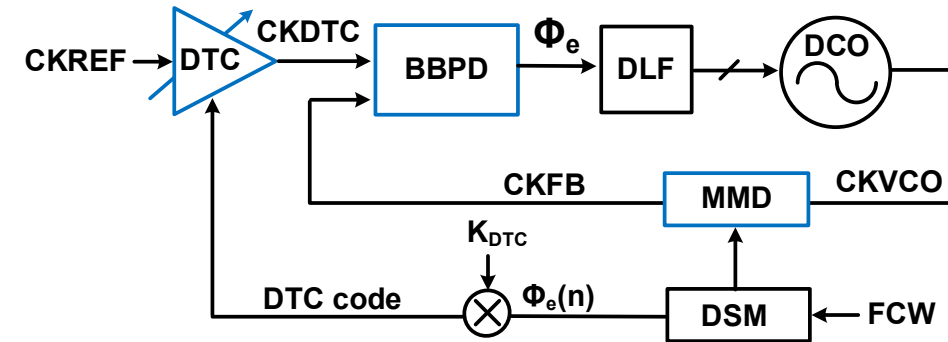
DTC-based PLL Variations – Digital PLLs

■ DTC-based ADPLL (1st order DSM)



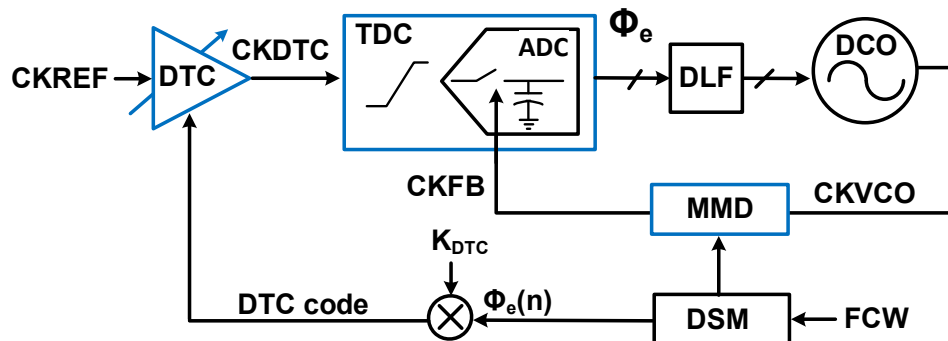
[N. Pavlovic ISSCC 2011]

■ DTC-based Bang-bang PLL



[D. Tasca JSSC Dec. 2011]

■ Digital sampling PLL

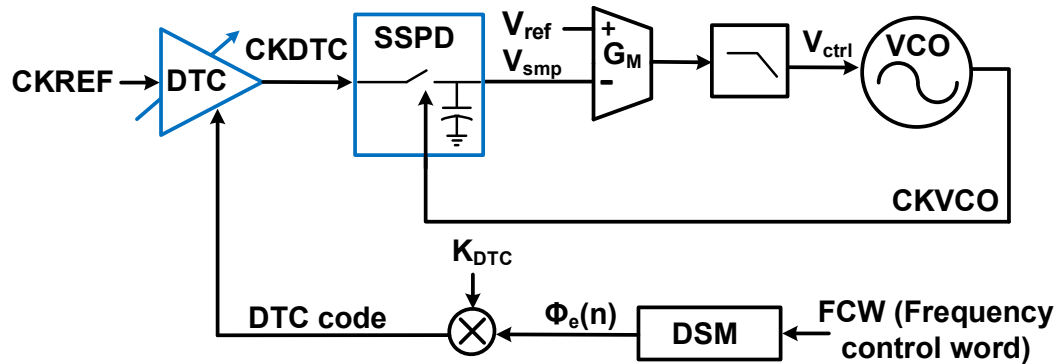


[X. Gao ISSCC 2016]

- Pros:**
- Φ_e is 1- or n-bit digital word
→ Used for LMS based K_{DTC} calibration
 - DLF small chip area
- Cons:**
- BBPD simpler than TDC (sampler+ADC), but need aux circuits to linearize its gain, and achieve fast locking
 - Need DCO

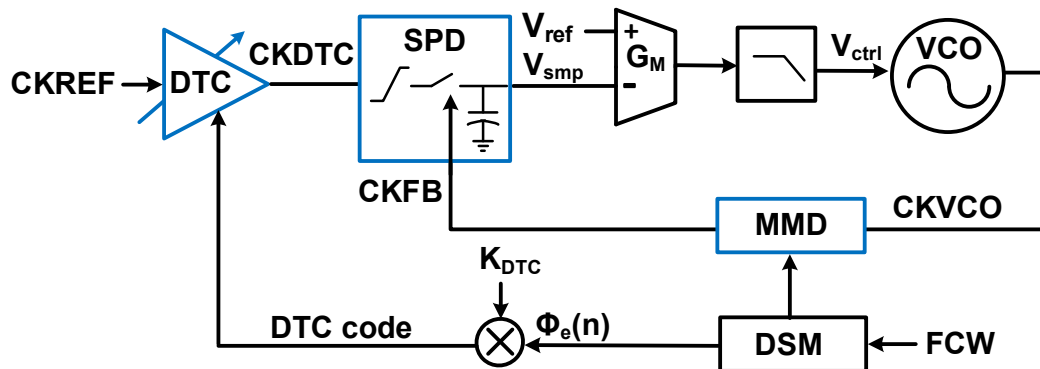
DTC-based PLL Variations – Analog PLLs

■ Analog PLL using sub-sampling PD



[K. Raczkowski JSSC May 2015]

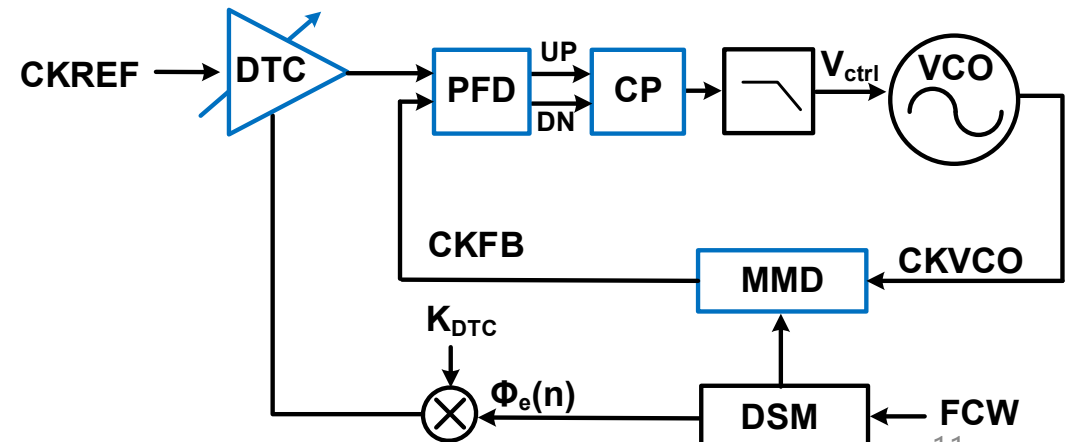
■ Analog PLL using sampling PD (SPD)



[W. Wu JSSC May 2019]

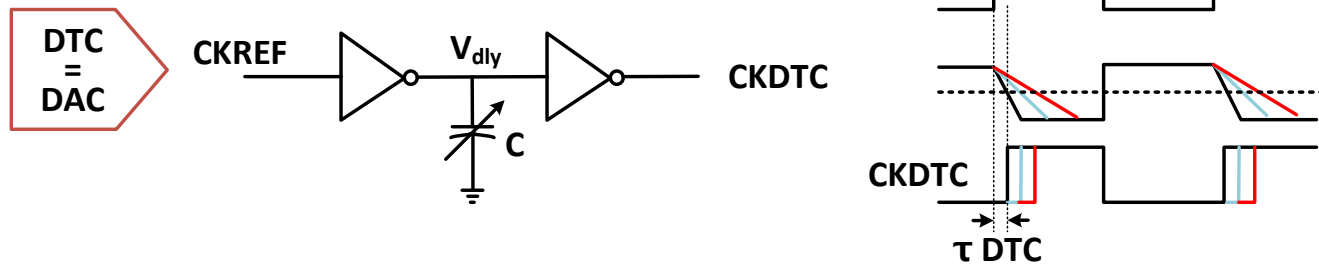
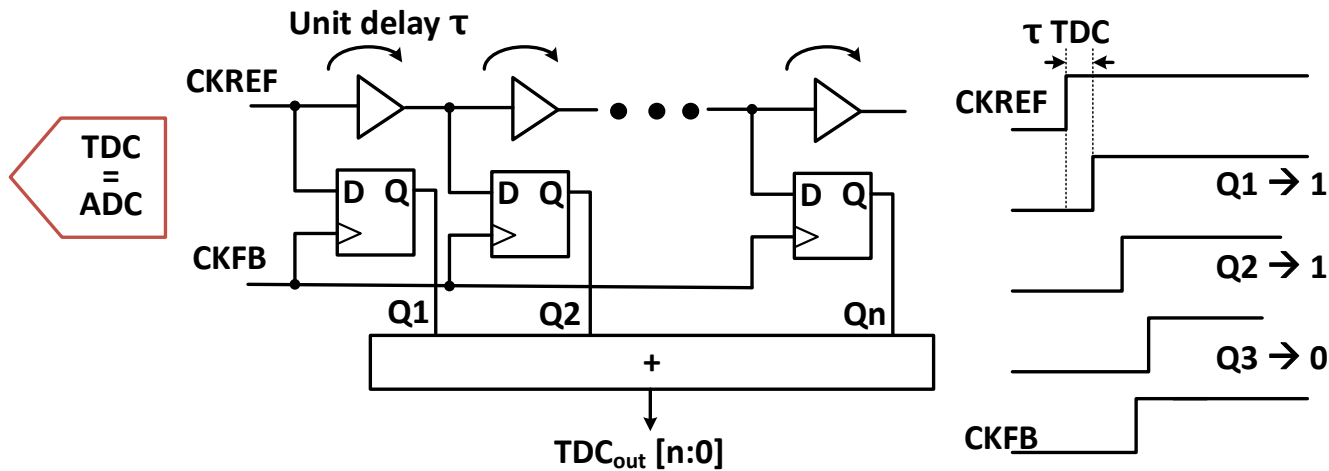
- Pros:**
- PD is a simple sample-and-hold circuit
 - K_{PD} is linear and well-defined vs. BBPD
 - No high-resolution TDC, no DCO
- Cons:**
- LF C_1 for optimal IPN $\leq 50\text{pF}$ typically (small overhead); type-I removes C_1
 - Need to digitize Φ_e for calibrations

■ DTC-assisted CP PLL



[P. Renukaswamy ISSCC 2023]

DTC vs. TDC as Phase Detector



■ TDC-based digital PLL

- In-band noise limited by TDC QN
- $\Delta t \sim 8\text{ps}$ in 14nm CMOS

- Finer $\tau \rightarrow$ Complexity \uparrow
- coarse-fine, Vernier delay line, timing amplifier, noise shaping, stochastic flash TDC, ...

■ DTC-based analog/digital PLL

- QN < other noise
- $\Delta t \sim 100\text{fs}$ in 14nm CMOS

- Broadly applicable

- Bang-bang

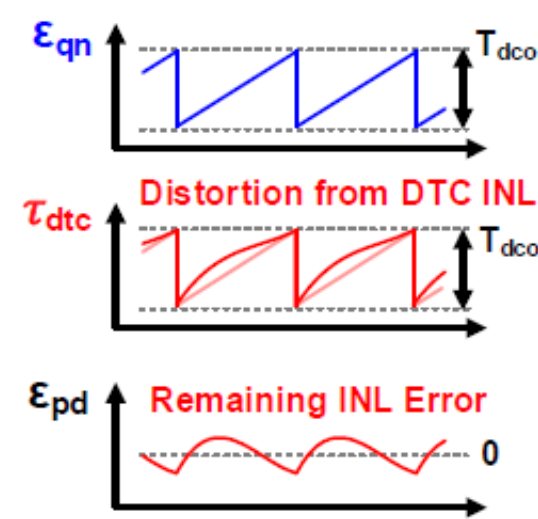
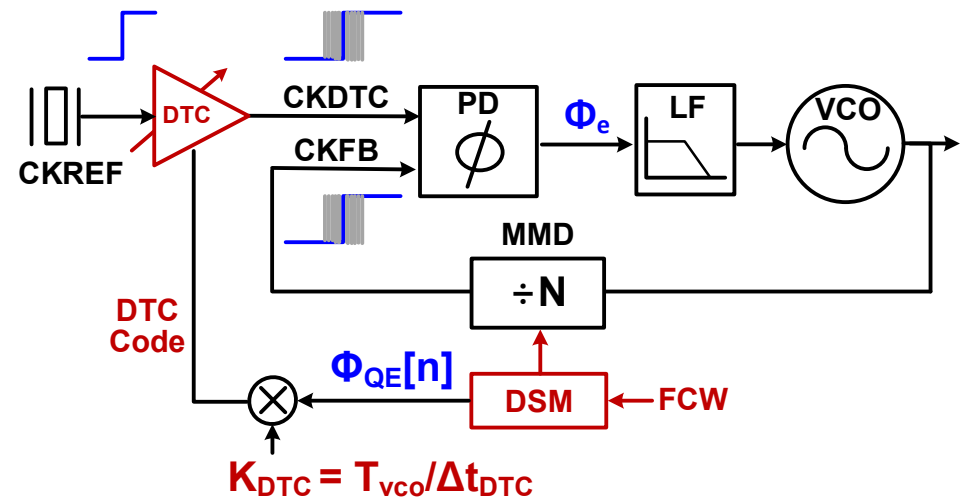
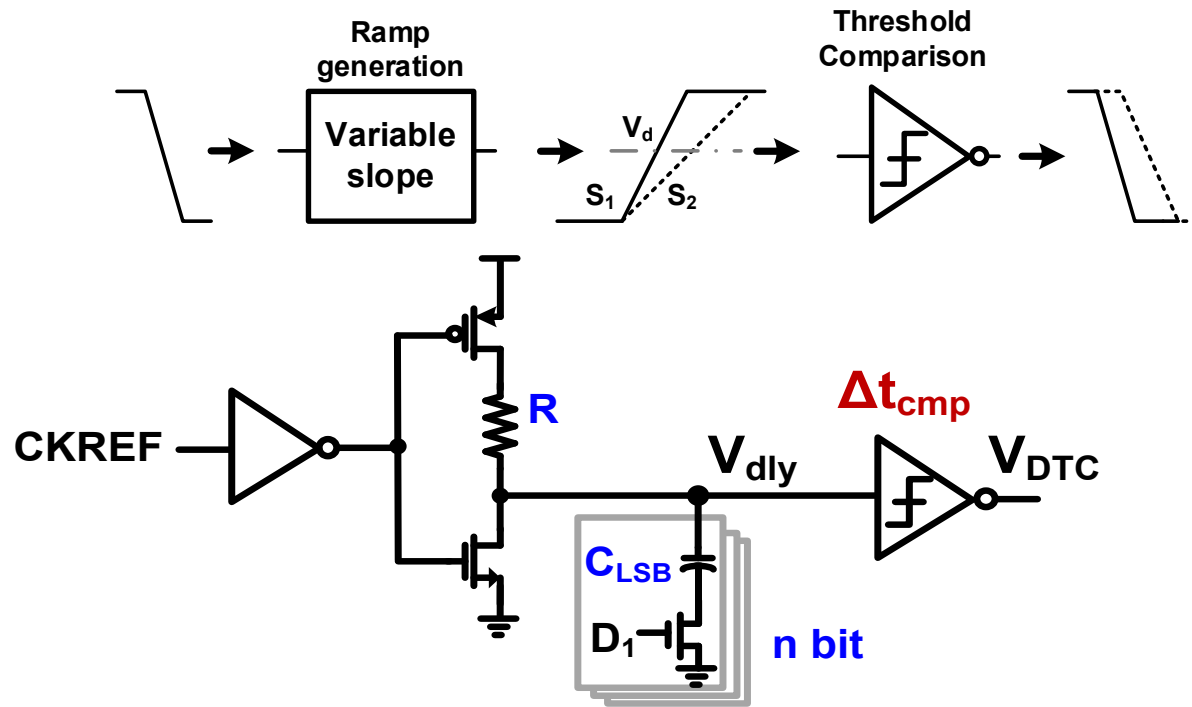
- Type-I/II (sub)sampling

- Digital (sub)sampling

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 - **RC Delay Based DTC**
 - **Other DTC Topologies for high linearity**
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RC Delay Based DTC- Variable Slope DTC



DTC contributes to PLL integrated PN (IPN)

- DTC RMS jitter → inband PN
- DTC quantization noise → inband PN
- DTC nonlinearity → frac. N spurs and noise folding

DTC Noise: Quantization Noise

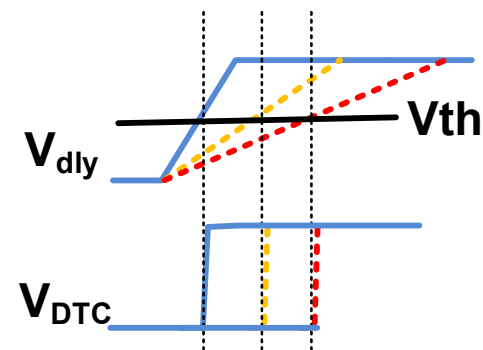
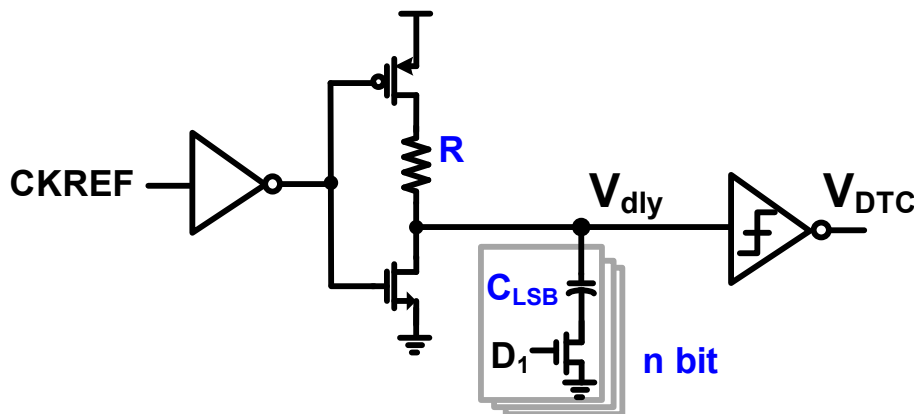
■ DTC QN

Unit delay $T_{res} = \ln 2 \cdot R \cdot C_{LSB}$

Input referred (at CKREF) $\Phi_{DTC, QN} = \frac{(2\pi \cdot T_{res})^2}{12} \cdot f_{ref}$

e.g., $T_{res} = 400\text{fs}$, $f_{ref} = 104\text{MHz}$, $\rightarrow \Phi_{DTC, QN, \text{ in dBc/Hz}} = -163\text{dBc/Hz}$

10bit \rightarrow total delay range, DR = 400ps, can support 2nd-order DSM with $f_{vco} > 5\text{GHz}$



DTC Noise: Thermal Noise

■ DTC thermal noise: delay stage and INV buffer

1) PN from delay stage:

Depends on slew of V_{dly} , thus, DTC code

SSB PN sampled at half VDD transition considering noise folding is

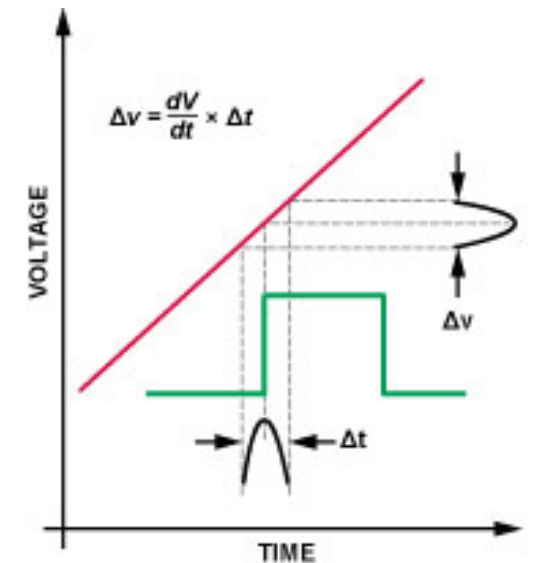
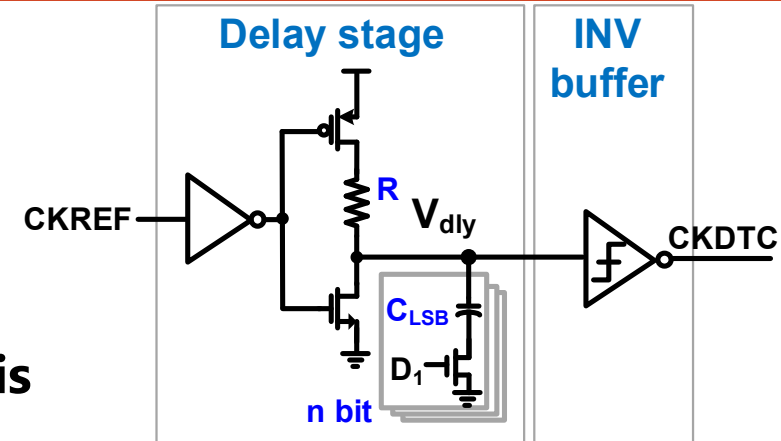
$$\mathcal{L} \cong 10 \cdot \log_{10} \left[\frac{1}{2} \left(\frac{2\pi \cdot f_{ref}}{k_{slew}} \right)^2 \cdot S_v^{folded}(f_m) \right], k_{slew} = \frac{1}{2RC} \text{ at } \frac{VDD}{2}, S_v^{folded}(f_m) \cong \frac{KT/C}{f_{out}/2}$$

$$\rightarrow \mathcal{L} \cong 10 \cdot \log_{10} \left[2kT \cdot f_{ref} \left(\frac{2\pi}{\ln 2} \right)^2 \cdot \frac{2^n \cdot T_{res}^2}{C_{LSB}} \right] \text{ at mid code,}$$

e.g., C_{LSB} needs $\geq 2fF$ for PN floor $< -171dBc/Hz$

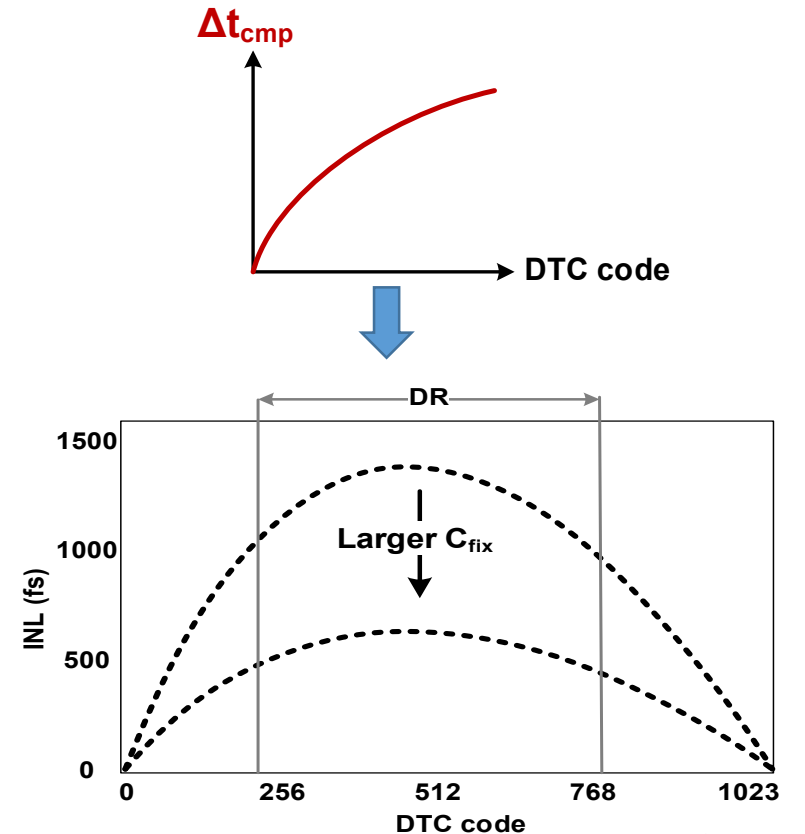
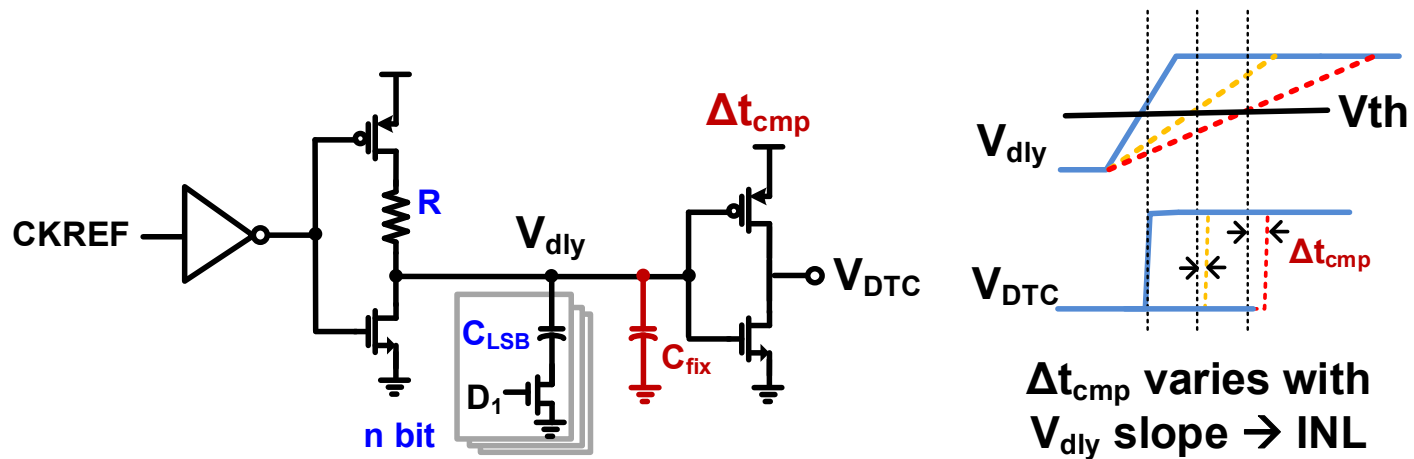
2) PN from INV buffer dominates:

INV BUF size up to hundreds of μm Width



DTC Nonlinearity – Static Distortion

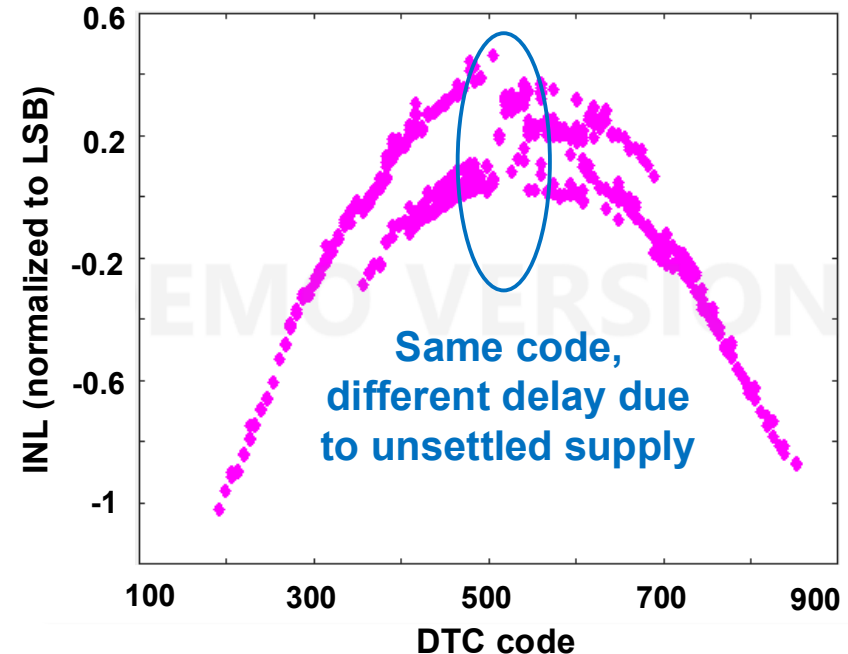
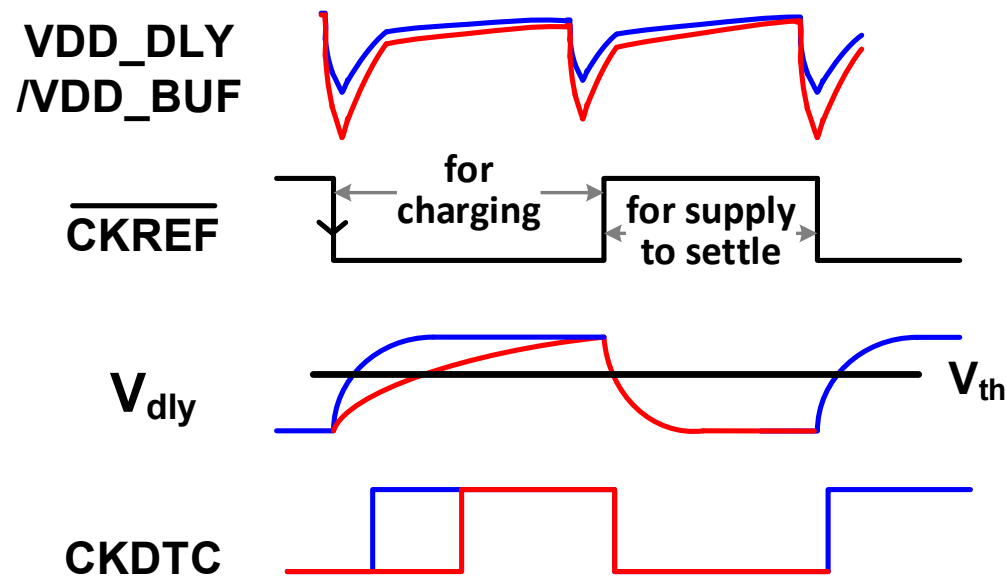
- **Matching of capacitor array** → not dominate as $C_{LSB} \geq 2fF$
- Common centroid layout, DEM to achieve $DNL = \pm 0.2$ LSB for 10bit DTC
- **Code/slope dependent Δt_{cmp}** → **INL, dominate!**
- Fixed cap. (e.g., 1~2 pF) reduces $INL < \sim 2$ LSB
- Parasitic cap of INV BUF serves as fixed cap



DTC Nonlinearity – Dynamic Distortion

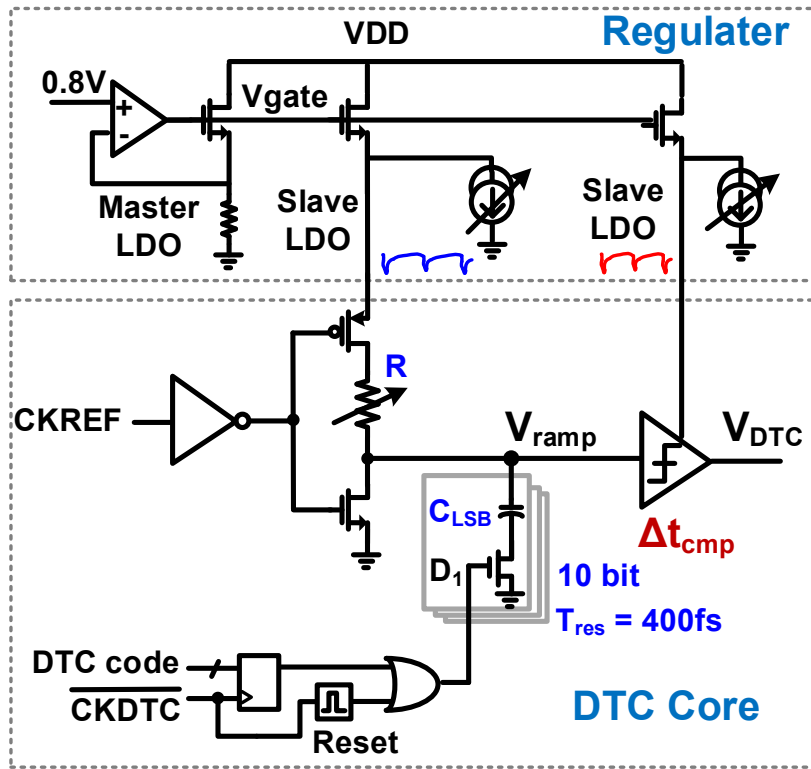
- Code-dependent supply settling error → INL, memory effect, dominate!

Large transient current at CKREF edges, supply dips and resettle each cycle



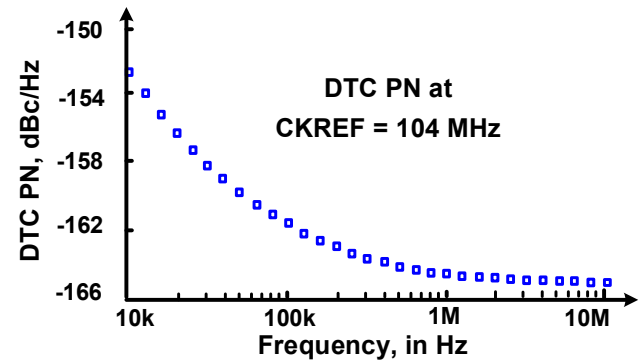
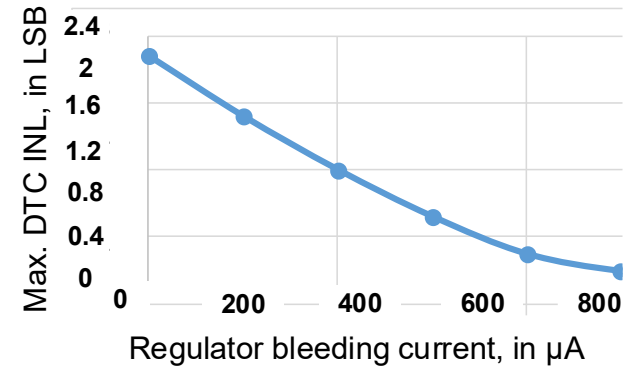
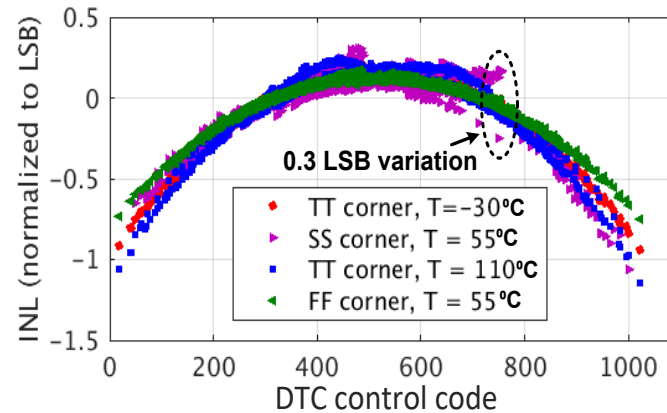
- Code-dependent charge on bottom plate of unit cap. array
→ INL, memory effect

High Performance DTC Design Example



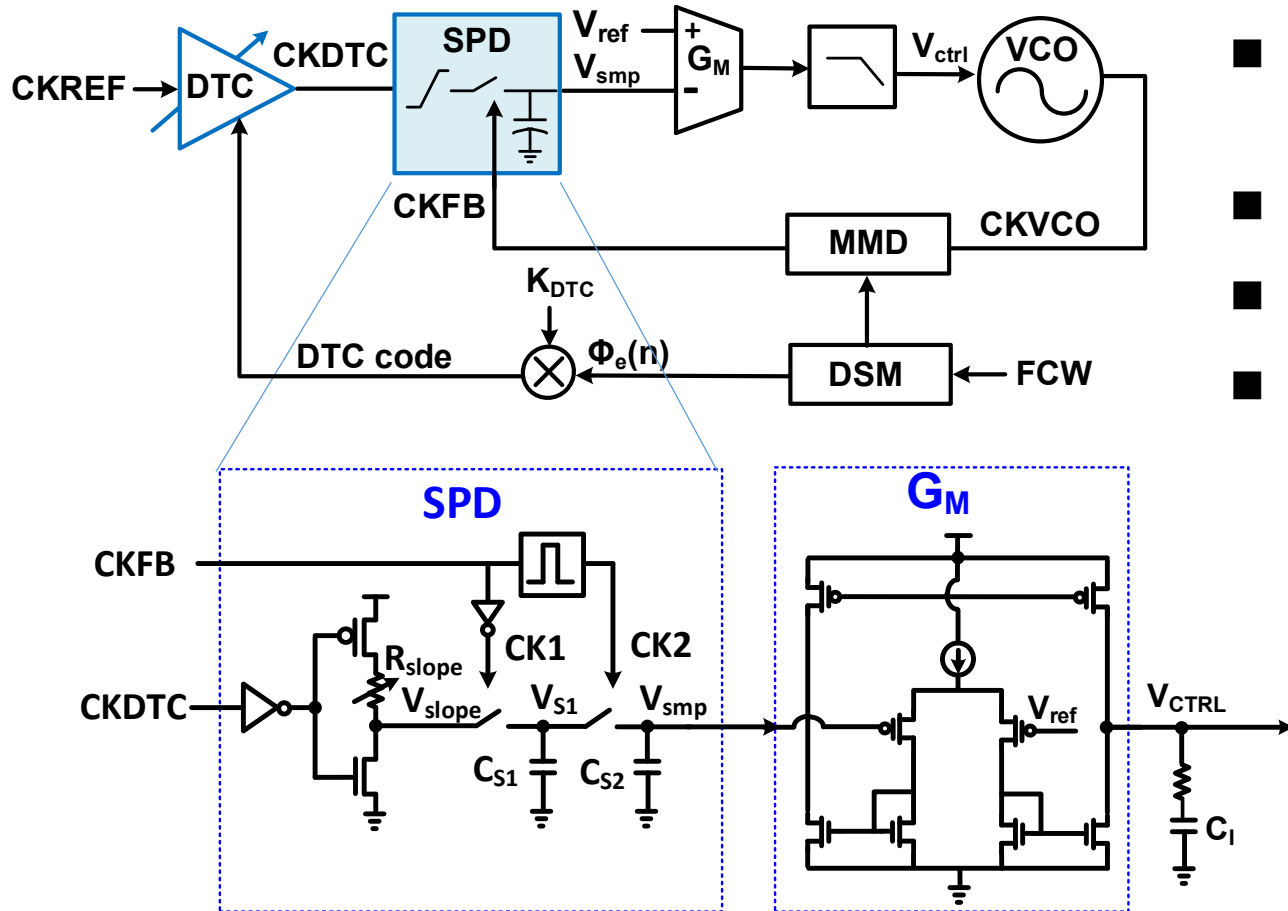
- DTC code reset to “1” each cycle to fully discharge tuning cap.

- Master-slave regulator for fast settling
- Bleeding current
↑ gm/C to speed up settling
at cost of higher I_{dc}
- Programmable R cover process variation

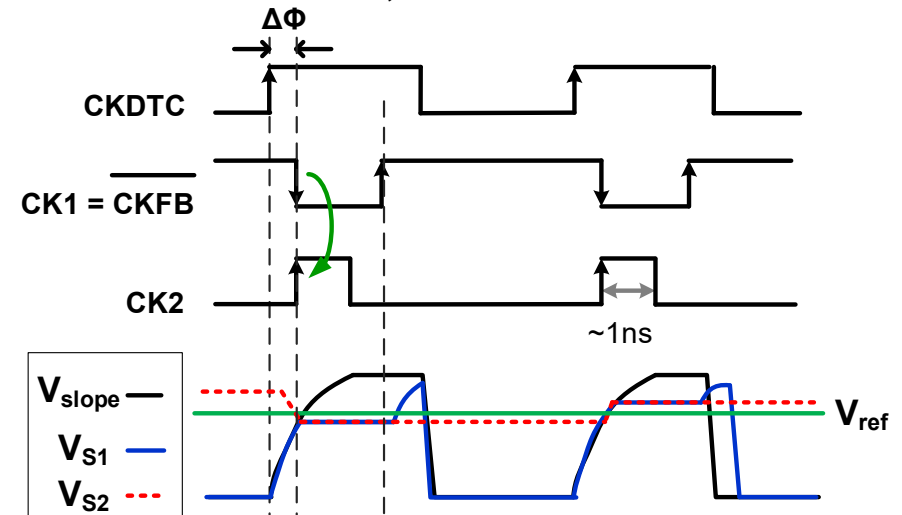


[W. Wu JSSC Dec 2021]

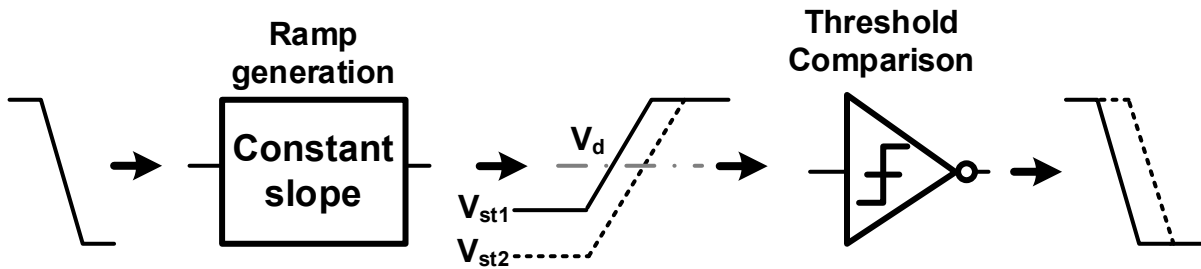
Continue with DTC-Assisted PD in Analog PLL



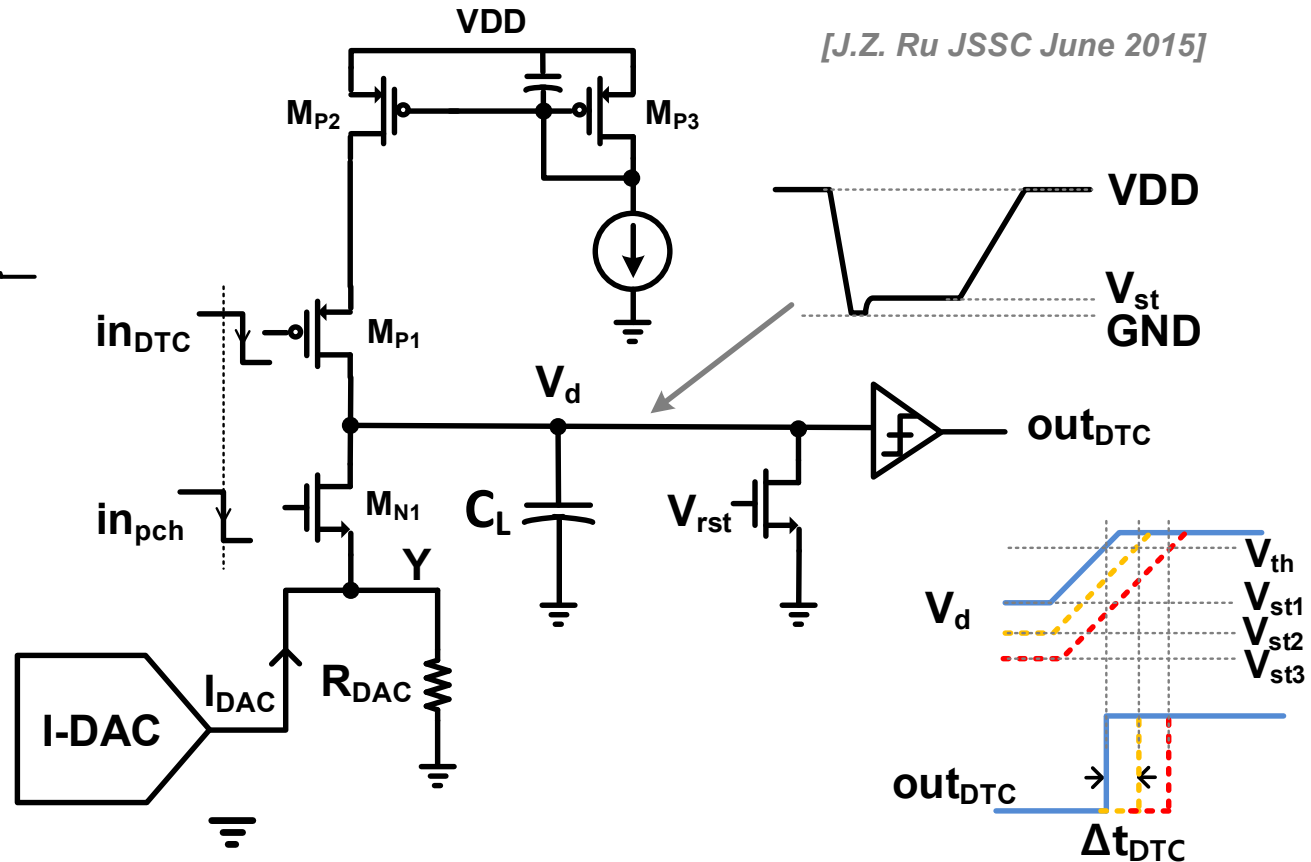
- V_{smp} is ZOH: 1st-order IIR filtering
- $K_{SPD} = K_{slope} / (2\pi f_{ref})$, for $K_{slope} = 6\text{GV/s}$, $f_{ref} = 104\text{ MHz}$, $\rightarrow K_{SPD} = 57/2\pi \gg K_{PD}$ in PFD-CP PLL
- G_M can be μA , its noise suppressed by high K_{SPD}
- Linearity of SPD not critical as DTC cancels QE
- Noise: $\sim 200\text{fF } C_{s1,2}$ results in $< -170\text{dBc/Hz}$



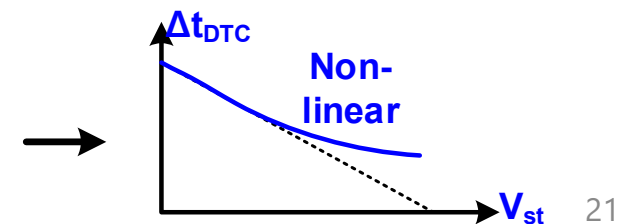
Constant Slope DTC (I/C)



- **Pros: no slope dependent delay**
- **Cons:**
 - **Nonlinearity sources:** I varies with code due to channel length mod., V_{st} settling error, etc.
 - **Flicker noise** from I
 - **Need high VDD** for high performance (e.g., 1.5V)



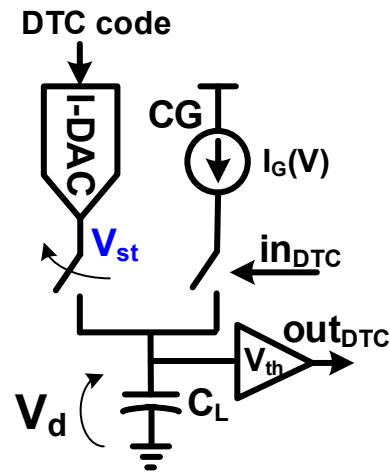
$$\Delta t_{DTC} = \int_{V_{st}}^{V_{th}} \frac{C_L(V)}{I_G(V)} dV$$



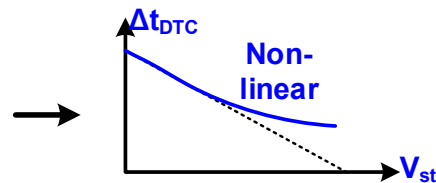
[J.Z. Ru JSSC June 2015]

Inverse-Constant-Slope DTC for Coarse-Fine DTC

Constant slope DTC

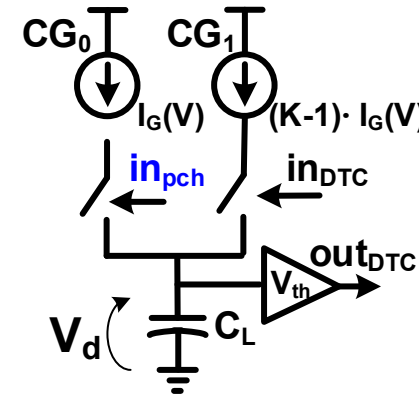


$$\Delta t_{DTC} = \int_{V_{st}}^{V_{th}} \frac{C_L(V)}{I_G(V)} dV$$

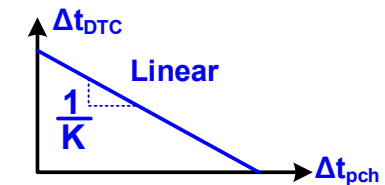


- DTC delay controlled by voltage V_{pch}
- Linearity affected to $I_G(V)$ and $C(V)$
- Linearity affected by DAC

ICS-DTC



$$\Delta t_{DTC} = \int_0^{V_{th}} \frac{C_L(V)}{K \cdot I_G(V)} dV - \frac{\Delta t_{pch}}{K}$$

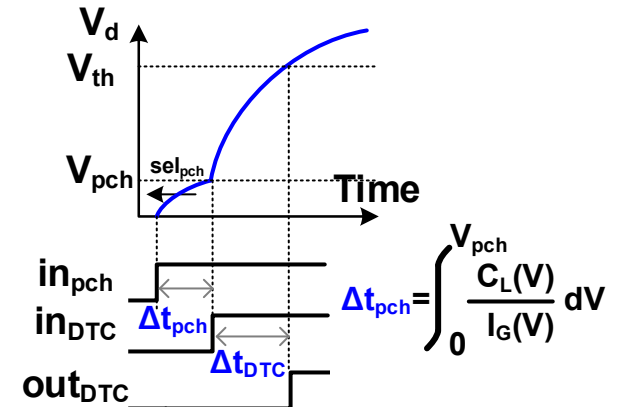


- controlled by time T_{pch}
- immunity to $I_G(V)$ and $C(V)$
- no need DAC

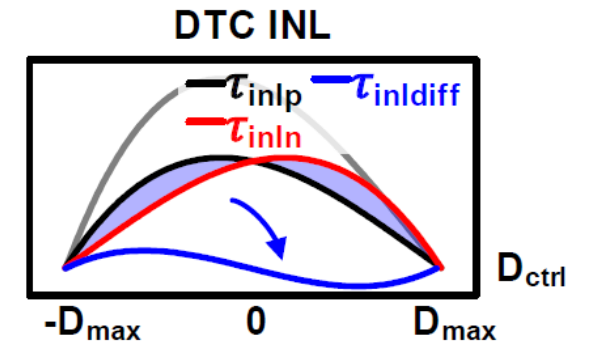
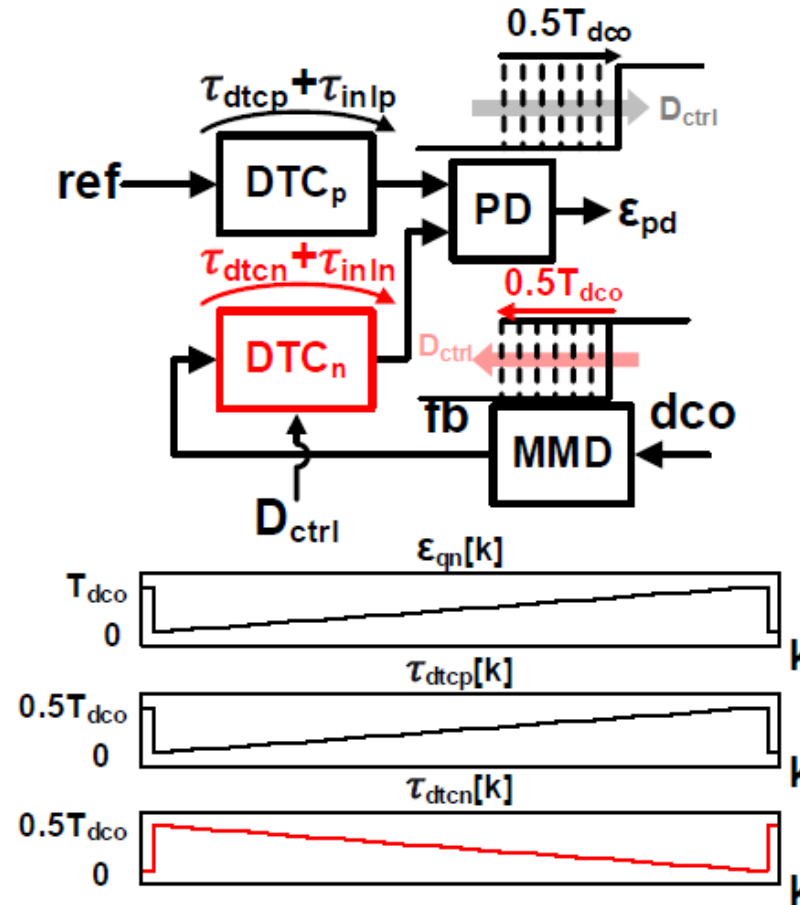
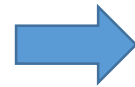
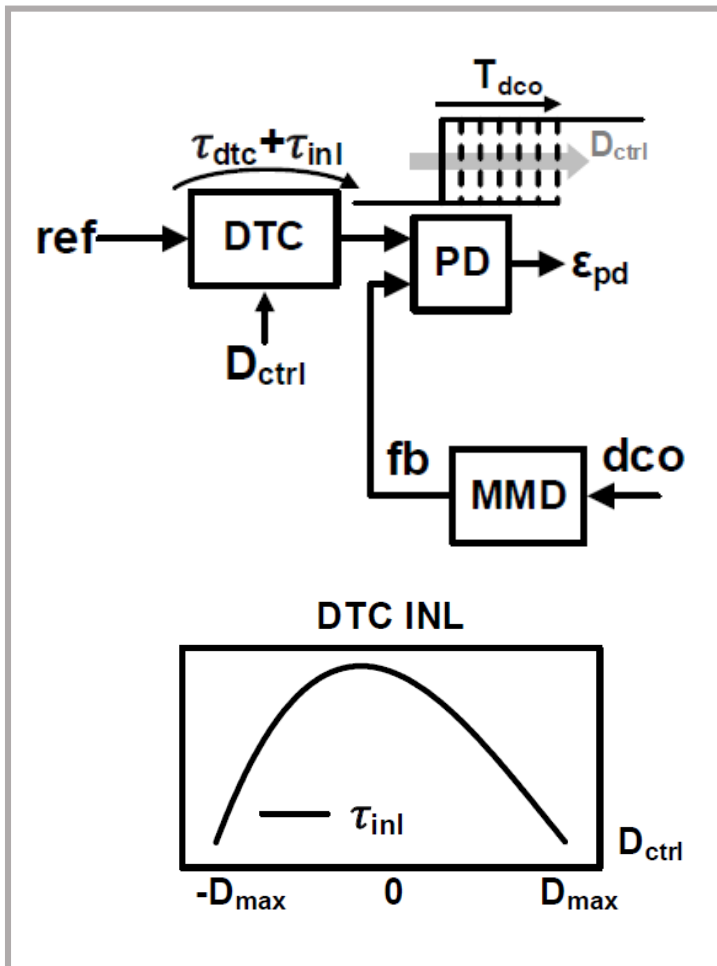
Too coarse, need another fine DTC

T_{pch} , T_{dTC} gen. uses DFFs and mux at f_{vco} 22

[S. M. Dartizio ISSCC 2023]



Pseudo-Differential DTC for Better Linearity



$$\begin{aligned} \tau_{indiff}(D_{ctrl}) &= \tau_{inlp}(D_{ctrl}) - \tau_{inln}(D_{ctrl}) \\ &= 2b_1 \frac{D_{ctrl}}{2D_{max}} \left(1 - 4\left(\frac{D_{ctrl}}{2D_{max}}\right)^2\right) \end{aligned}$$

only odd-symmetric components

[D. Xu ISSCC 2024]

- Two half-range DTCs \rightarrow each DTC has better linearity
- Even-symmetric INL cancels

Digital Assisted Techniques for Linear DTC

- **DTC nonlinearity calibration (NLC)**
- **Reverse-Concavity Variable-Slope DTC**
- **DTC range reduction with multiple VCO/DCO phases**

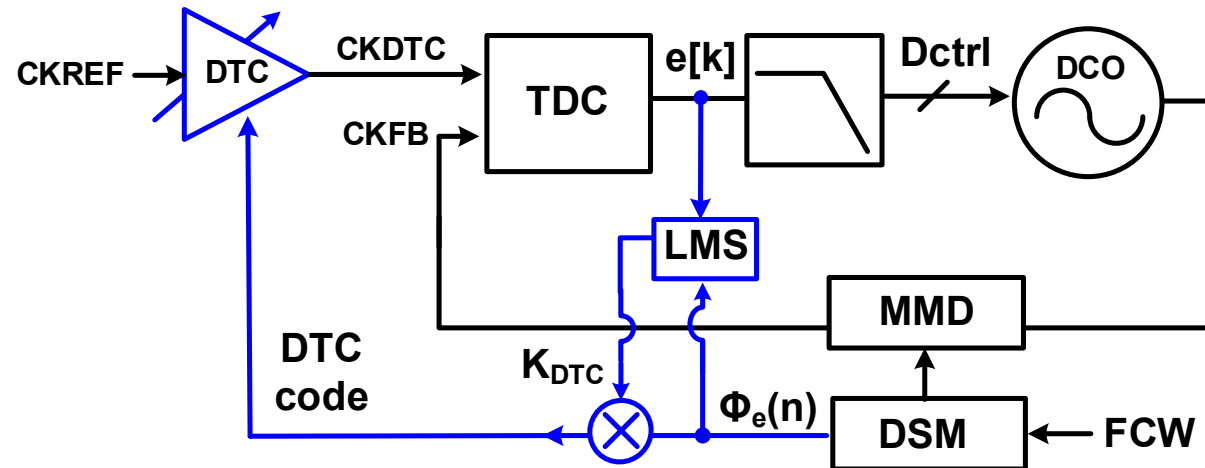
Will be discussed next in digital calibration section

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 - **DTC Gain CAL, NLC, Range Reduction**
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Adaptive Filter Used in DPLL for Calibration

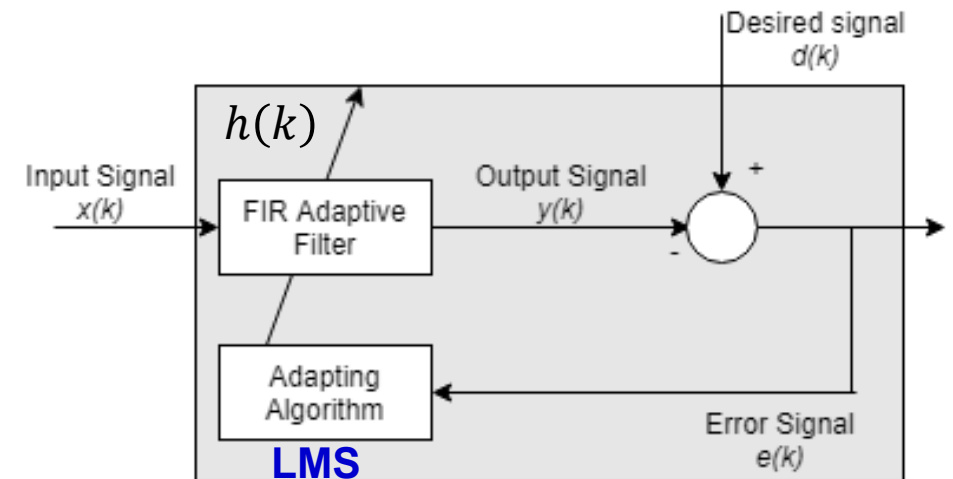
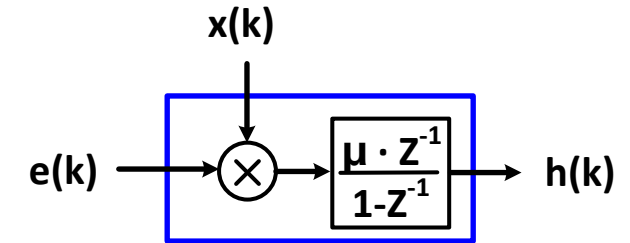
DTC gain need to be accurate to ensure QN cancellation



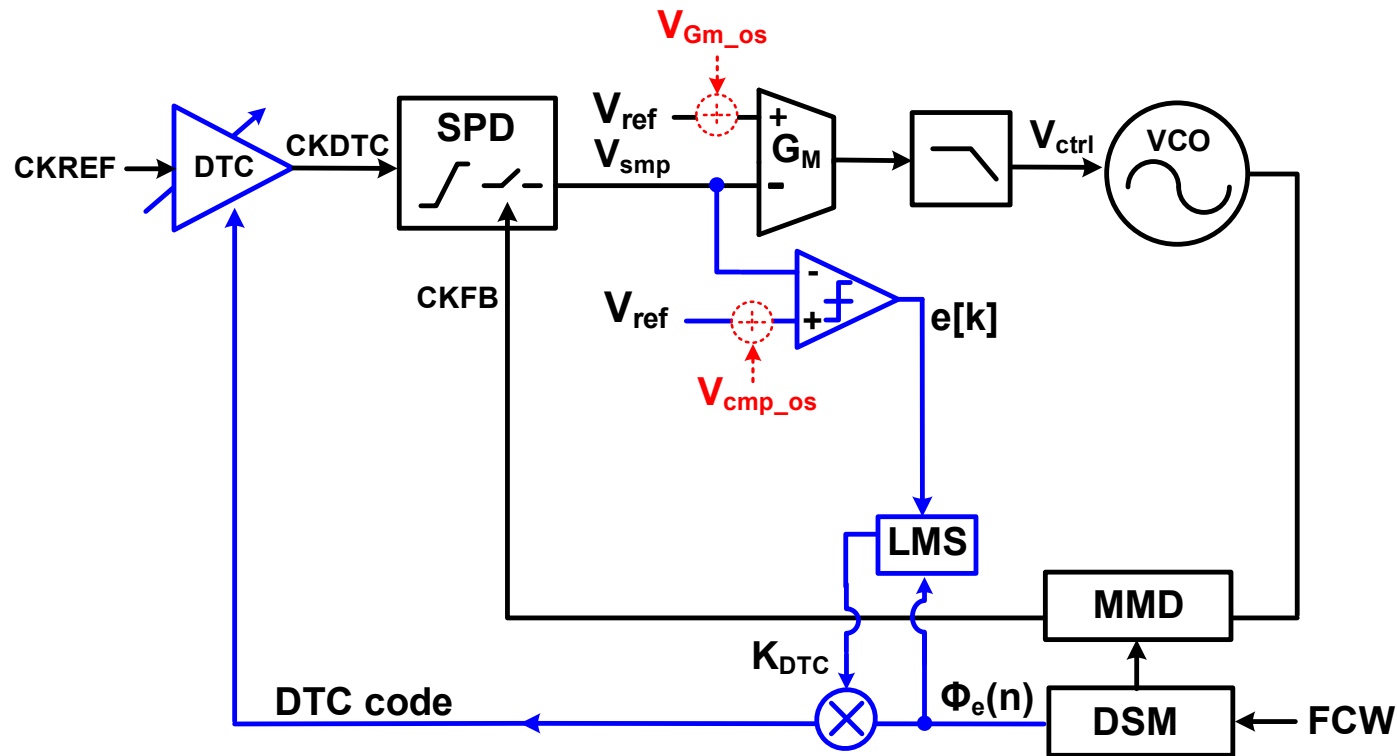
For DTC gain calibration:

- $h(k)$ is K_{DTC}
- Input signal $x(k)$: accumulated QE due to DSM, i.e., Φ_e .
- Error signal $e(k)$: phase error between CKREF and CKFB
- CKDTC phase is the output signal $y(k)$
- CKFB phase is the desired output signal $d(k)$

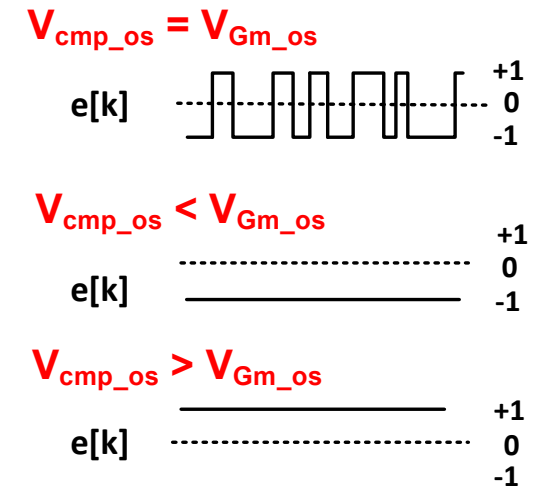
LMS adaptation



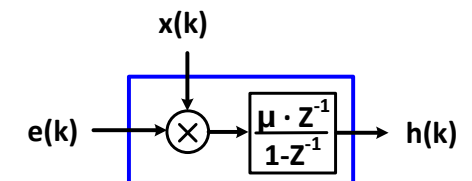
DTC Gain CAL in Analog Sampling PLL [1]



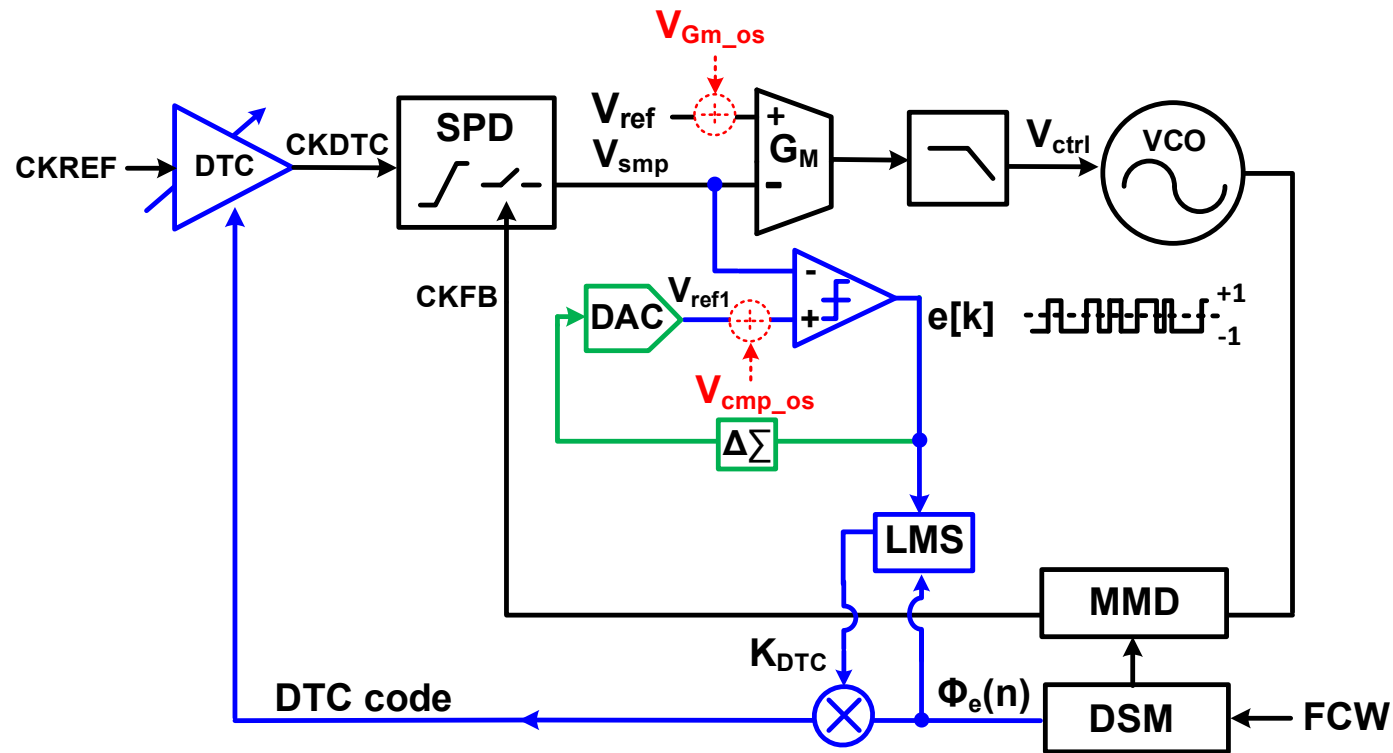
■ Issues of comparator, G_M offset



LMS adaptation



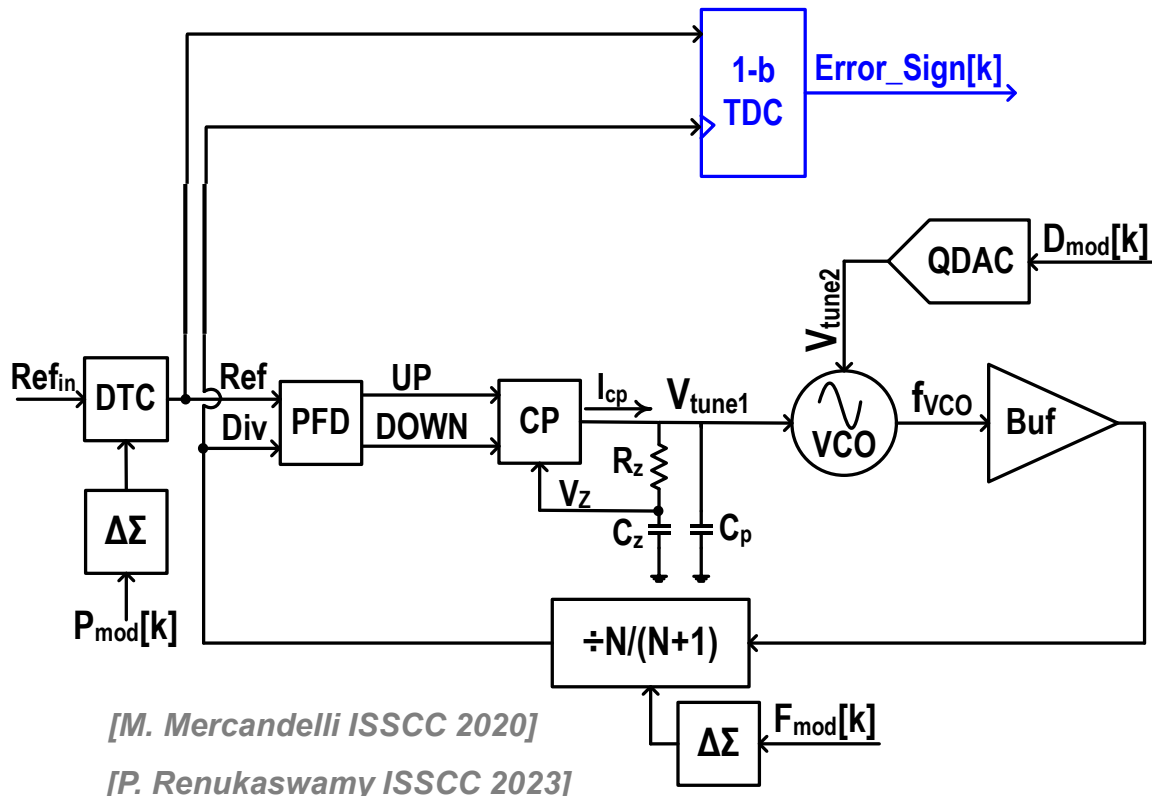
DTC Gain CAL in Analog Sampling PLL [2]



- Single comparator gets sign of PHE, $e[k] \rightarrow$ LMS
- Remove DC offset in $e[k]$ by adjusting V_{ref1}
- Simple 1-bit ΔV -DAC is sufficient

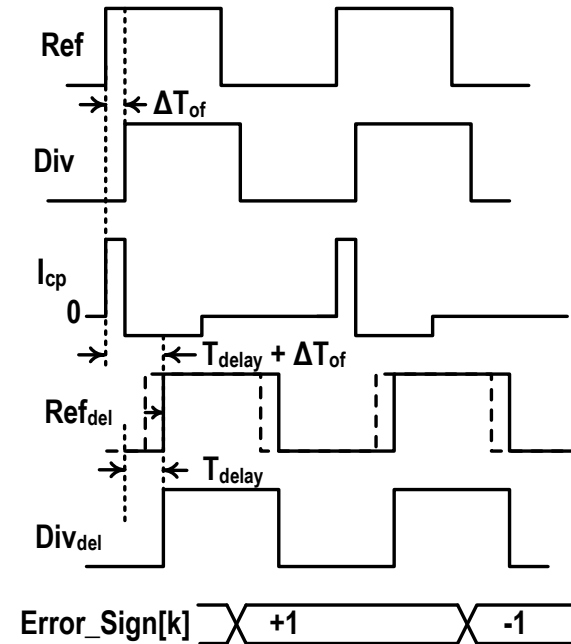
Alternative Way to Get Zero-Mean PHE Sign [1]

- Phase offset (ΔT_{of}) varies over PVT
- Use coarse-fine DTC to compensate $\Delta T_{of} \rightarrow$ POC-DTC tracks ΔT_{of} over PVT
- Error_Sign[k] is zero-mean after convergence

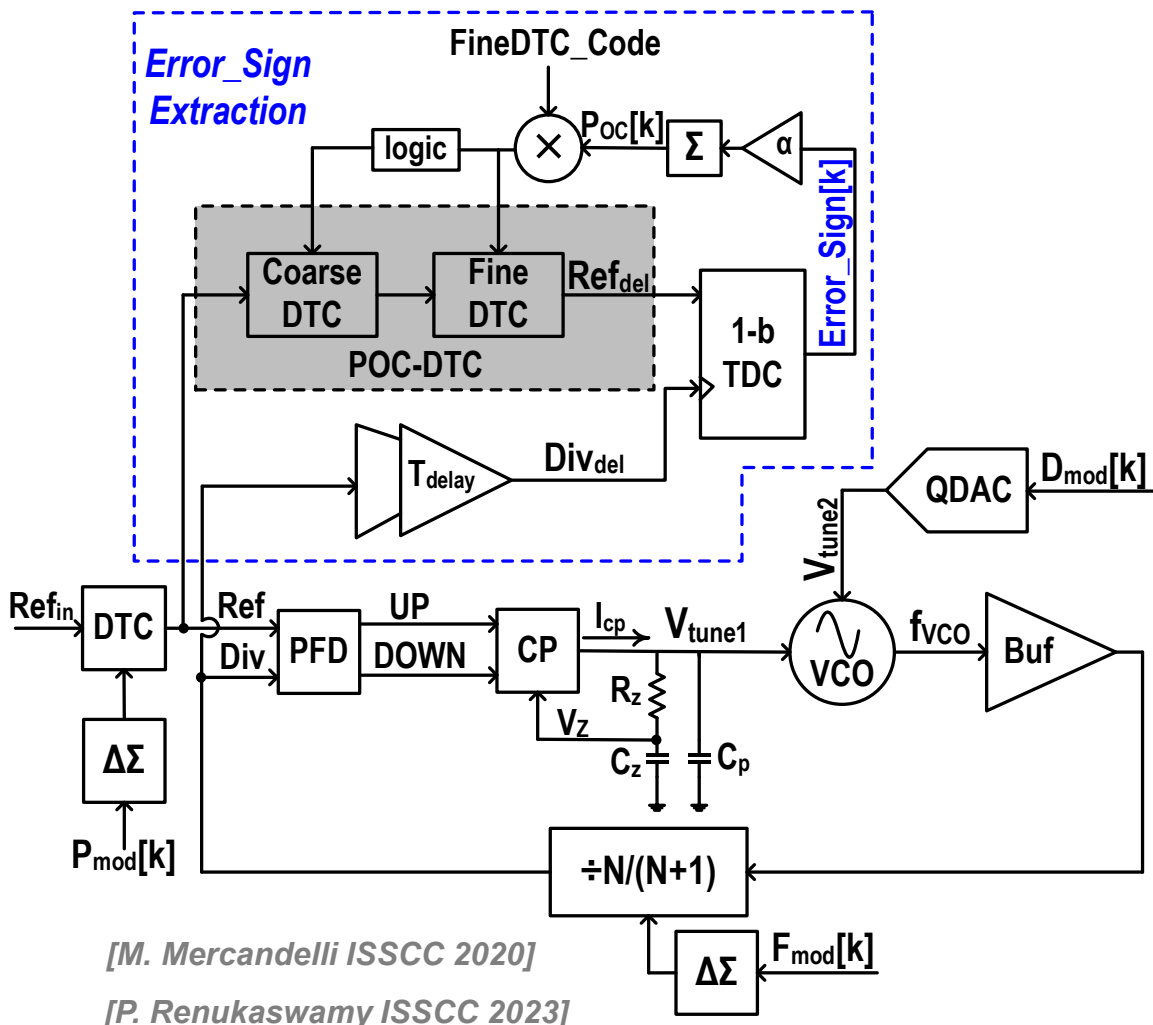


[M. Mercandelli ISSCC 2020]

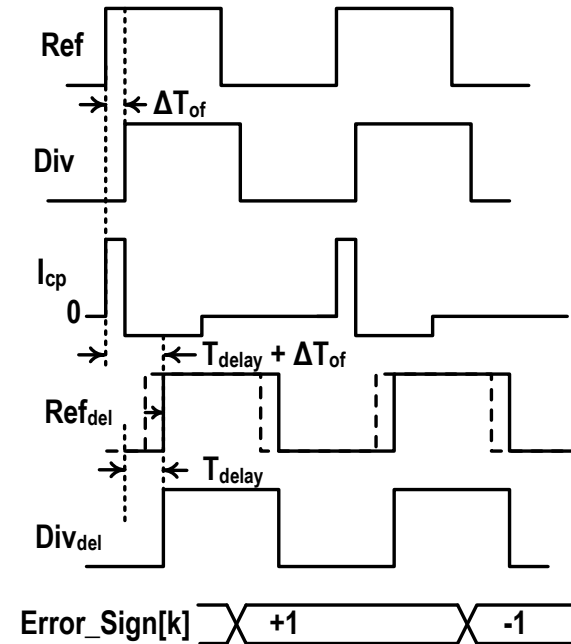
[P. Renukaswamy ISSCC 2023]



Alternative Way to Get Zero-Mean PHE Sign [2]

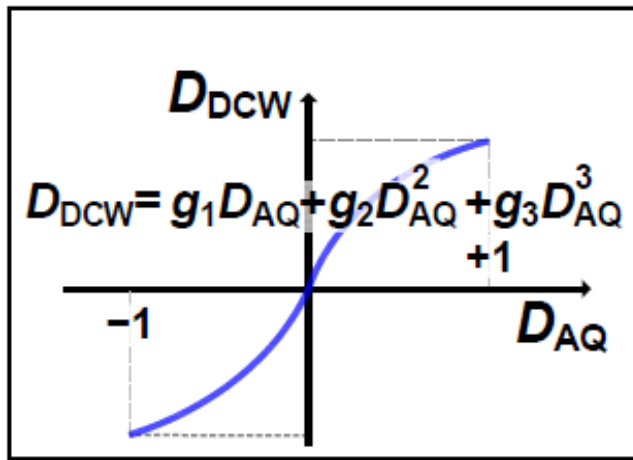


- Phase offset (ΔT_{of}) varies over PVT
- Use coarse-fine DTC to compensate $\Delta T_{of} \rightarrow$ POC-DTC tracks ΔT_{off} over PVT
- Error_Sign[k] is zero-mean after convergence

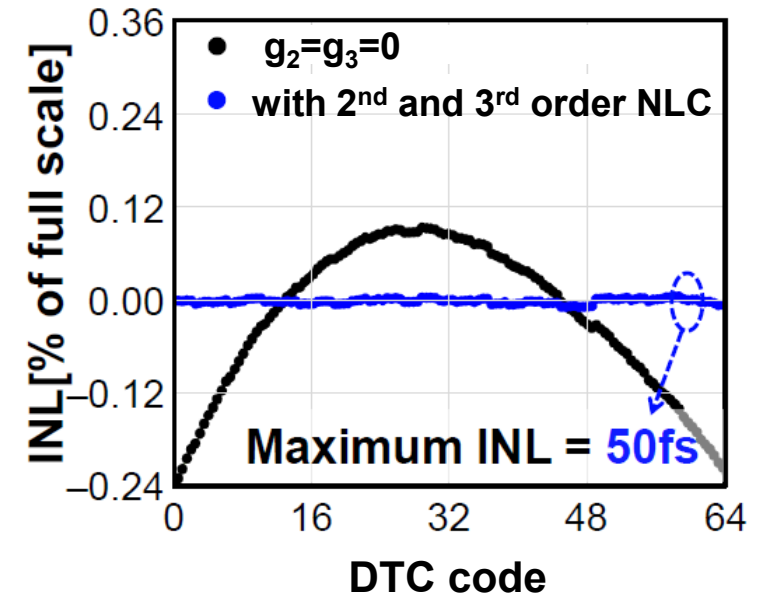
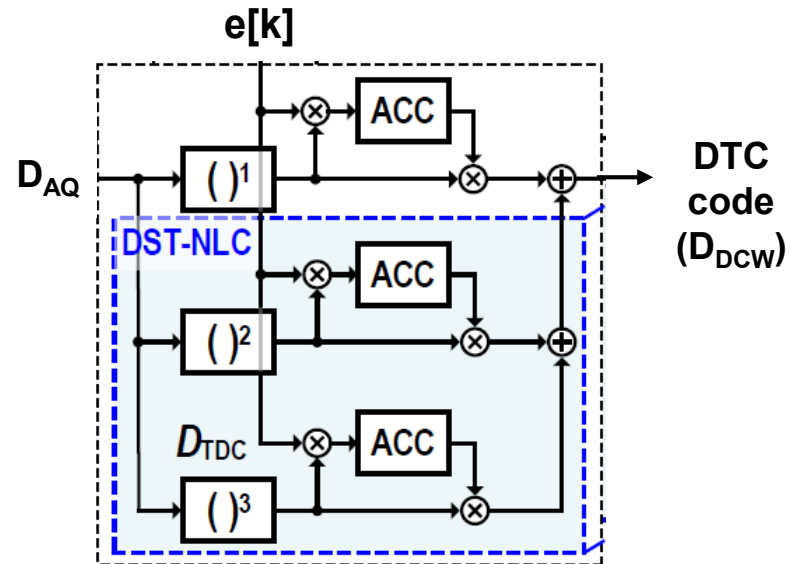


DTC NLC – Polynomial CAL

- Intrinsic INL of a RC-delay based DTC has strong 2nd order NL
- Use LMS loop to get DTC gain (g_1), as well as its 2nd and 3rd order component (g_2 and g_3); D_{AQ} is accumulated DSM phase error, $\Phi_e(n)$

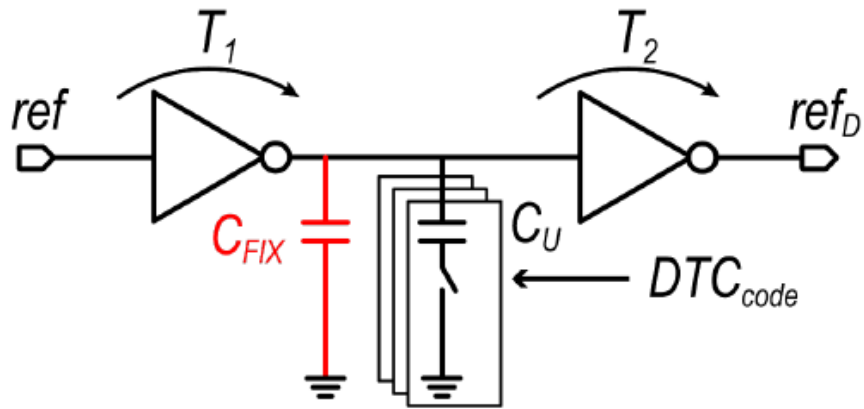


[H. Park ISSCC 2021]

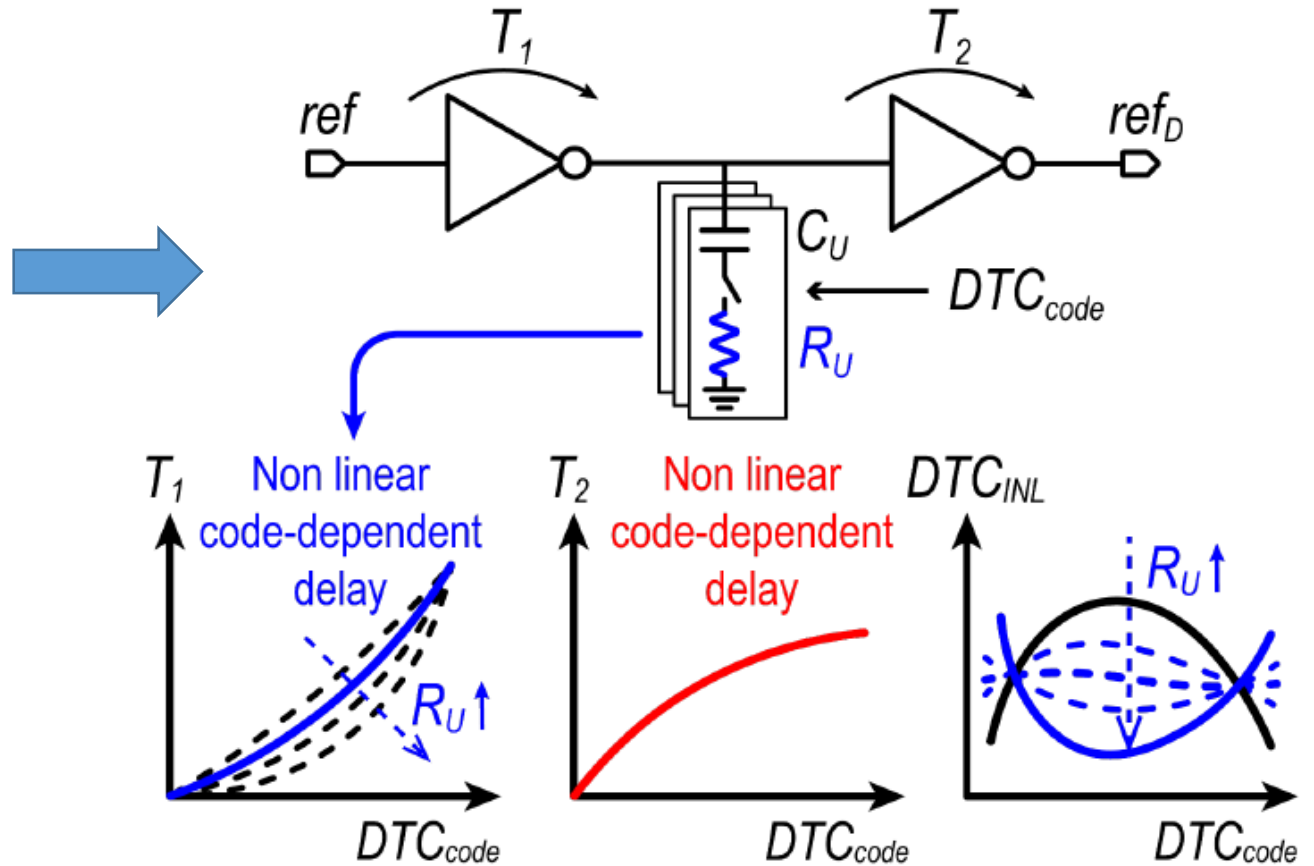


Reverse-Concavity Variable-Slope DTC

Conventional variable-slope DTC



- Change R_U to compensate NL
- Voltage DAC controls R_U
- Adaptation loop find DAC code



[M.Rossoni ISSCC 2024]

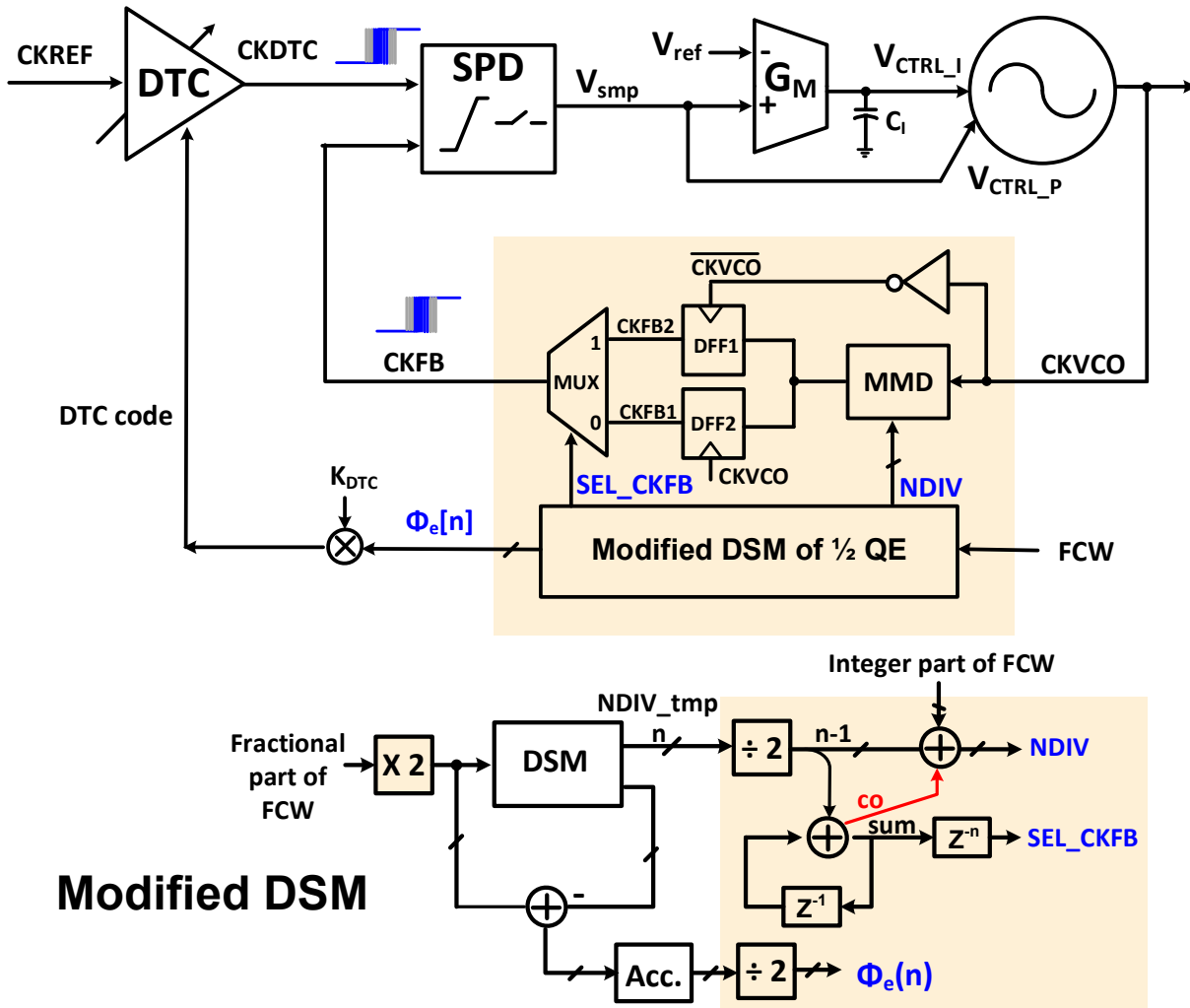
DTC Range Reduction for Better Linearity

Recap DTC tradeoffs

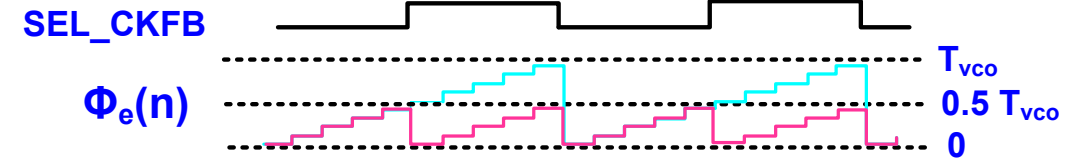
- DTC Delay Range (DR): $DR \propto T_{VCO}$, DSM order
- DTC QN $\propto t_{res}^2$ $DR = 2^n \cdot t_{res} = 2^n \cdot \ln 2 \cdot RC_{LSB}$
- DTC thermal noise $\mathcal{L} \propto DR$: $\mathcal{L} \cong 10 \cdot \log_{10} \left[2kT \cdot f_{ref} \frac{(2\pi)^2}{\ln 2} \cdot DR \cdot R \right]$
- DTC linearity better for smaller DR
- DTC power $\propto DR^2$

$DR \downarrow \rightarrow$ less bits, faster slope, lower noise and power, more linear

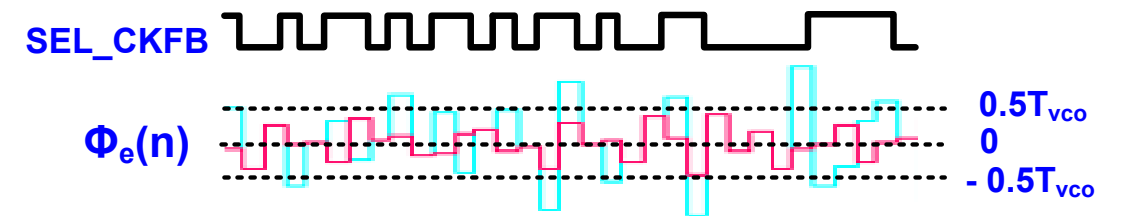
Half DTC Range with Two VCO Phases



Example of a MASH1 DSM



Example of a MASH1-1 DSM



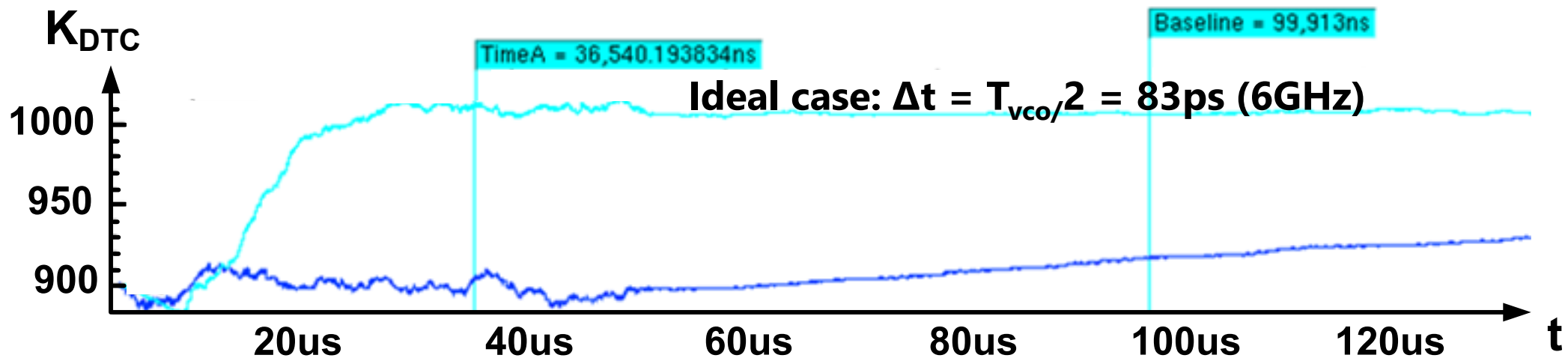
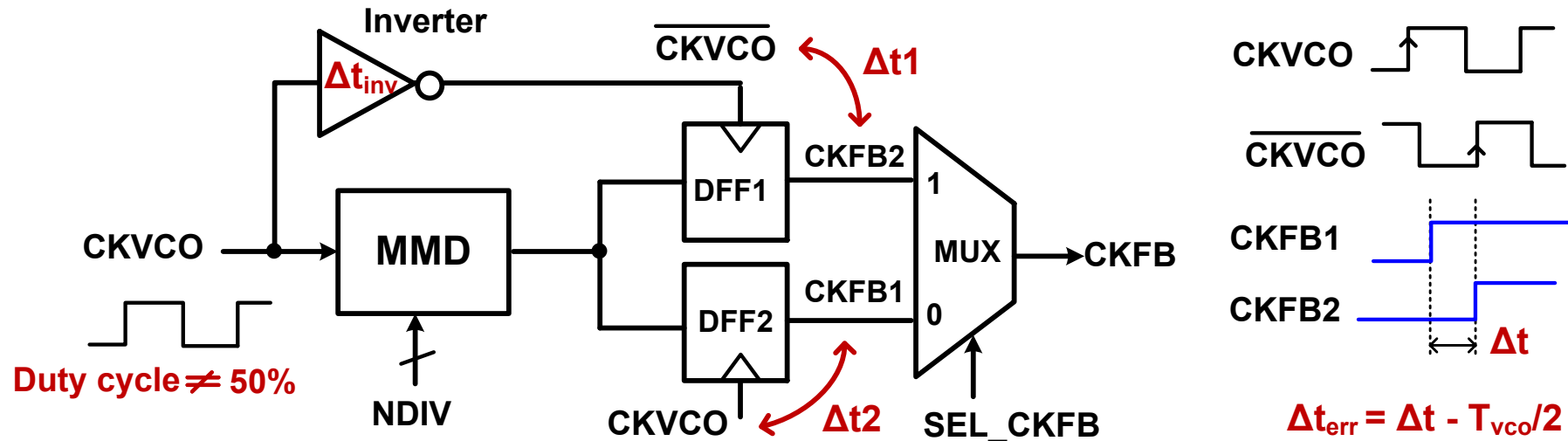
— Proposed MMD and DSM

— Conventional MMD and DSM

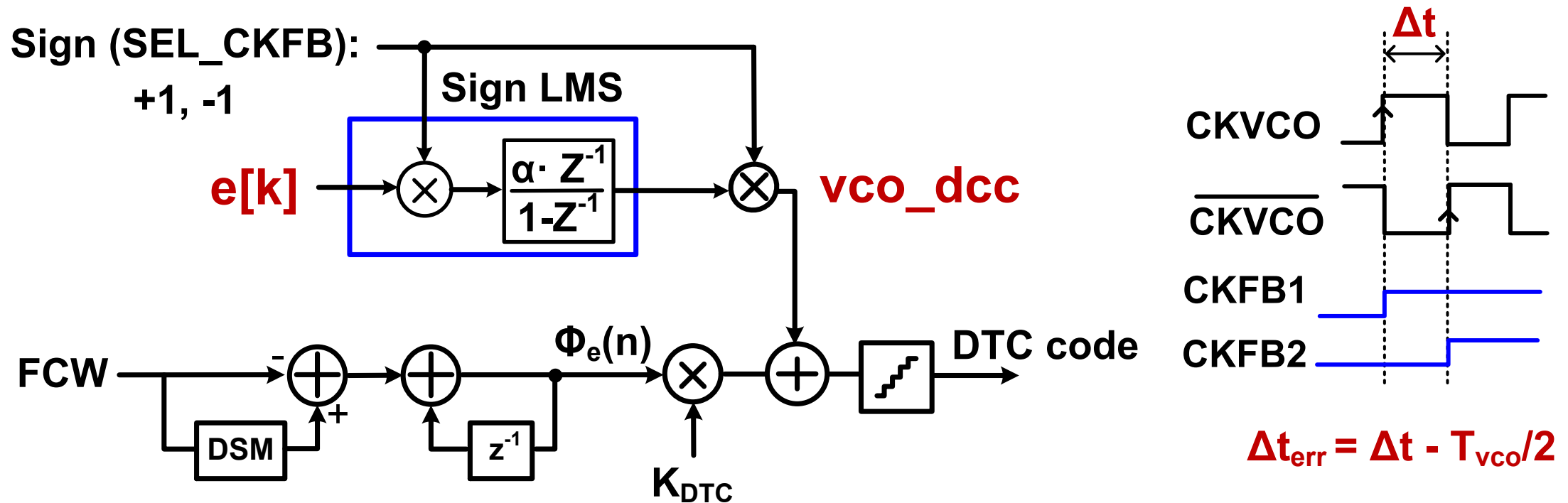
■ Switching from CKFB1 to CKFB2 introduces a half-period delay

[W. Wu ISSCC 2021]

VCO Duty Cycle Error Disrupts K_{DTC} CAL

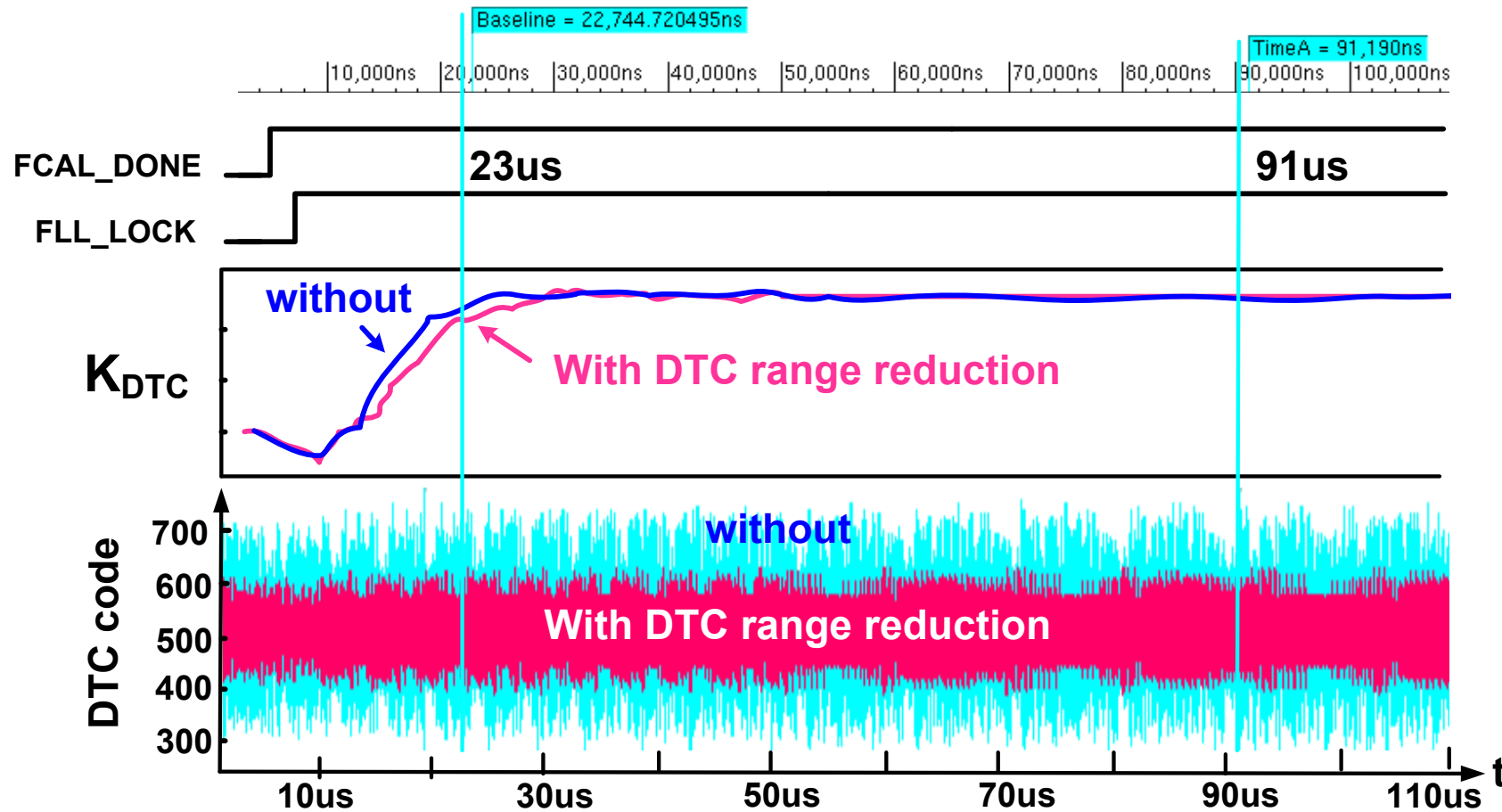


VCO Duty Cycle Calibration



- SEL_CKFB = +1 \rightarrow push back CKDTC by $\Delta t_{err}/2$
- SEL_CKFB = -1 \rightarrow pull-in CKDTC by $\Delta t_{err}/2$

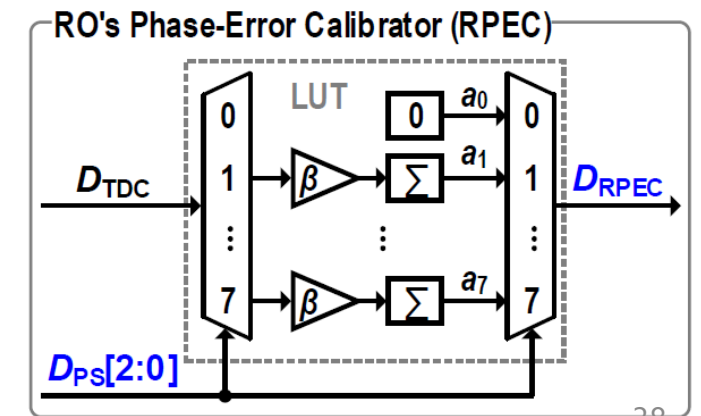
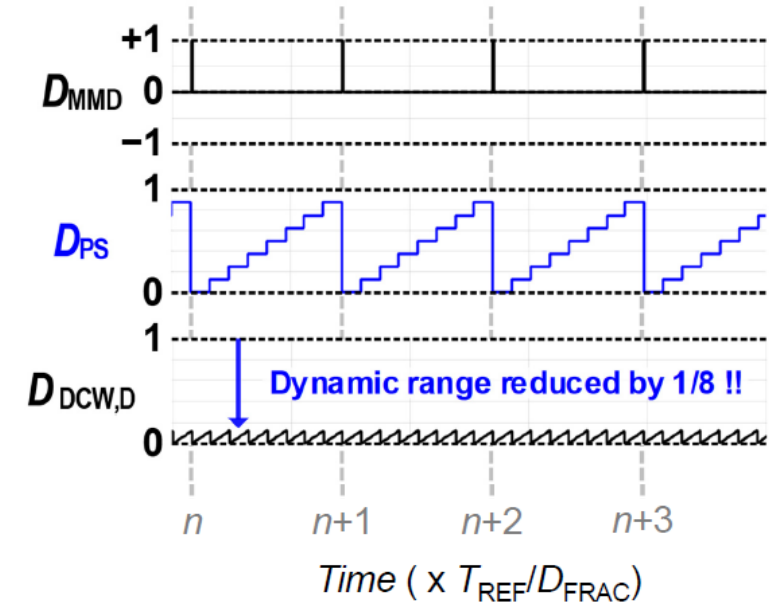
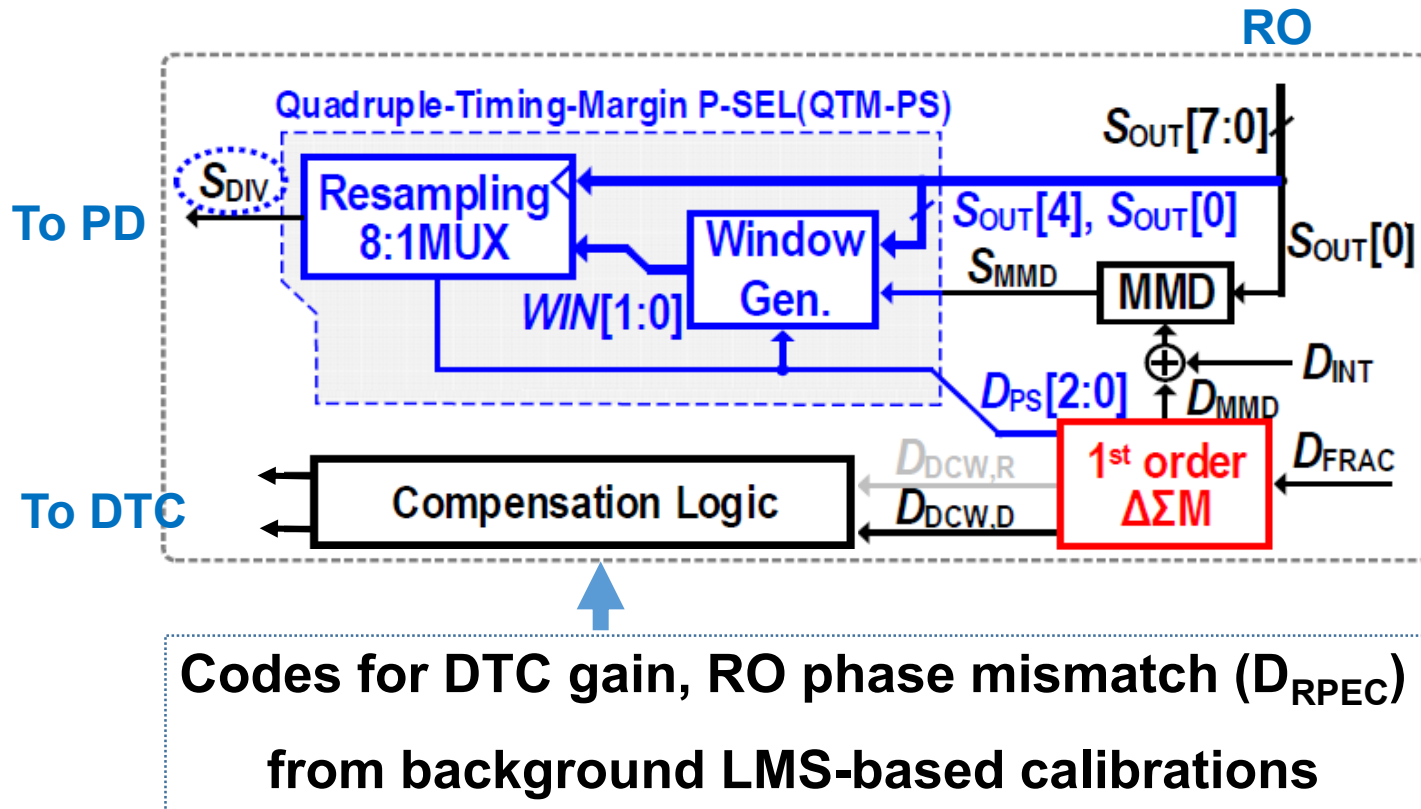
Simulated K_{DTC} CAL and DTC Code



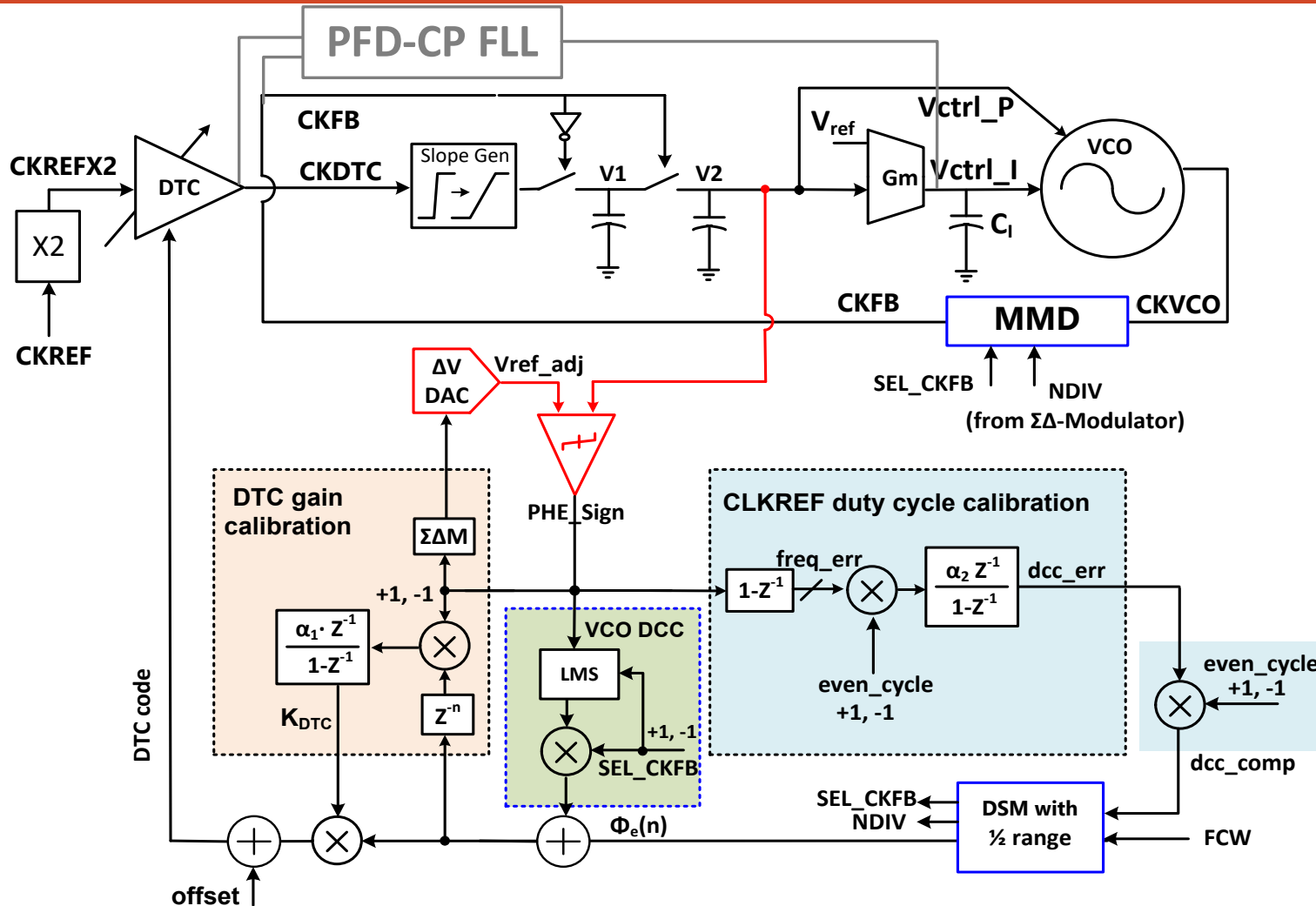
- **KDTC converges < 30 μs , even with 12% VCO duty cycle error**
- **DTC code range is halved**

1/8 DTC Range Reduction Using 8 RO Phases

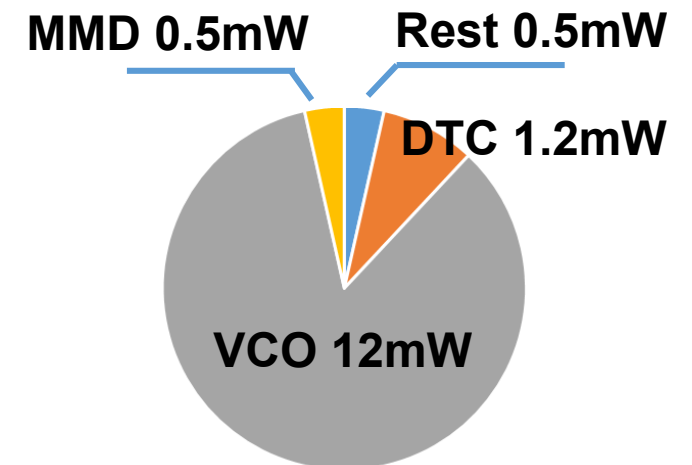
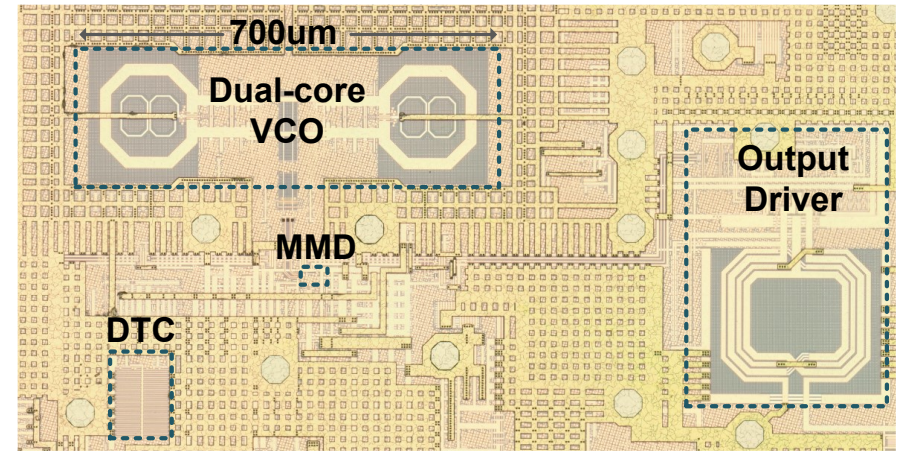
- $S_{OUT}[7:0]$ are 8 phases from differential ring oscillator
- Timing of QTM-PS is stringent



Low Jitter Sampling Analog PLL Example

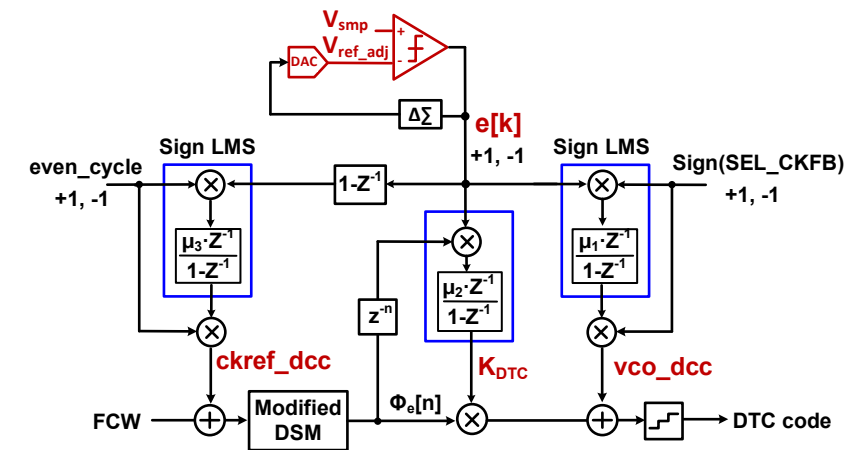
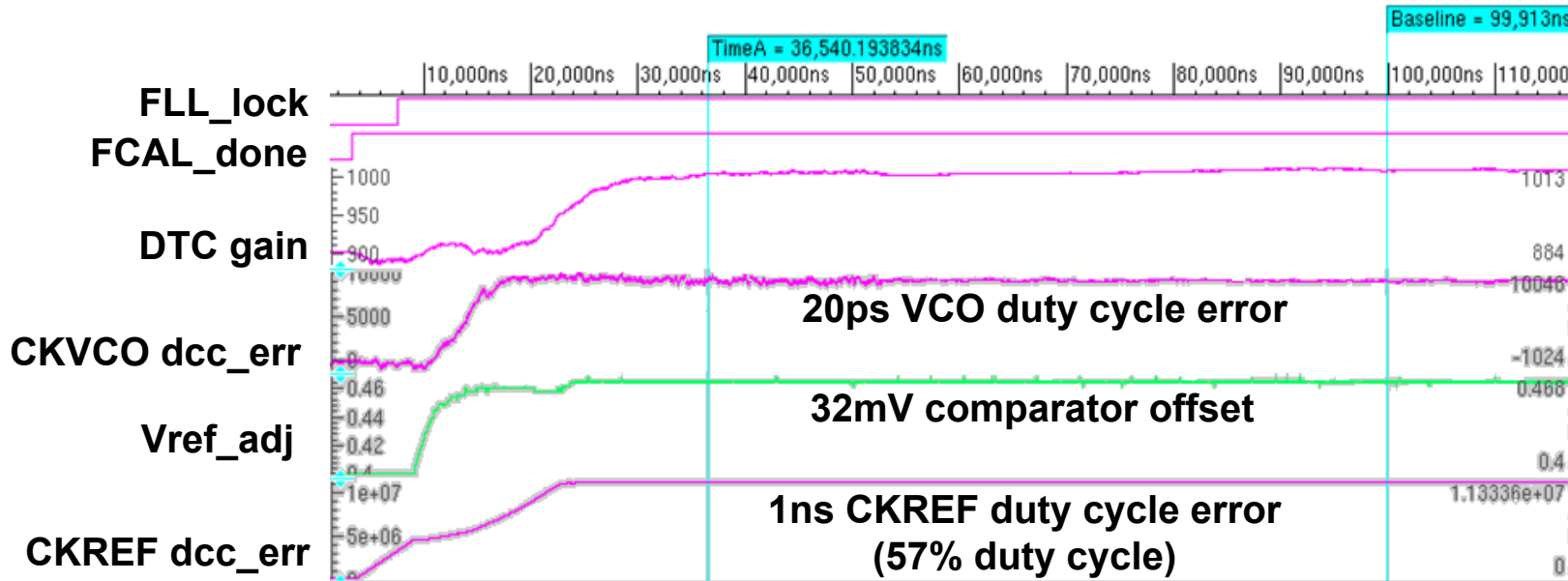


■ 14nm FINFET, Core 0.31mm²



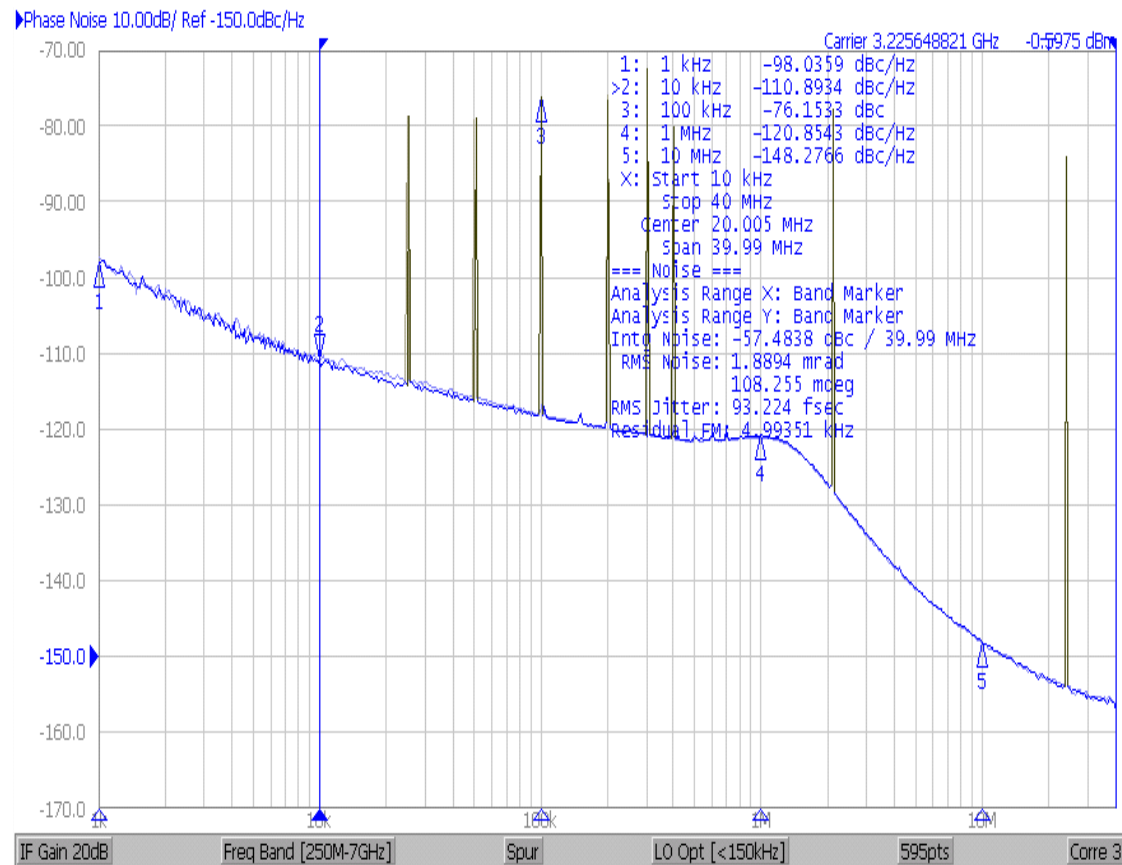
[W. Wu ISSCC 2021]

Simulated Background Calibration

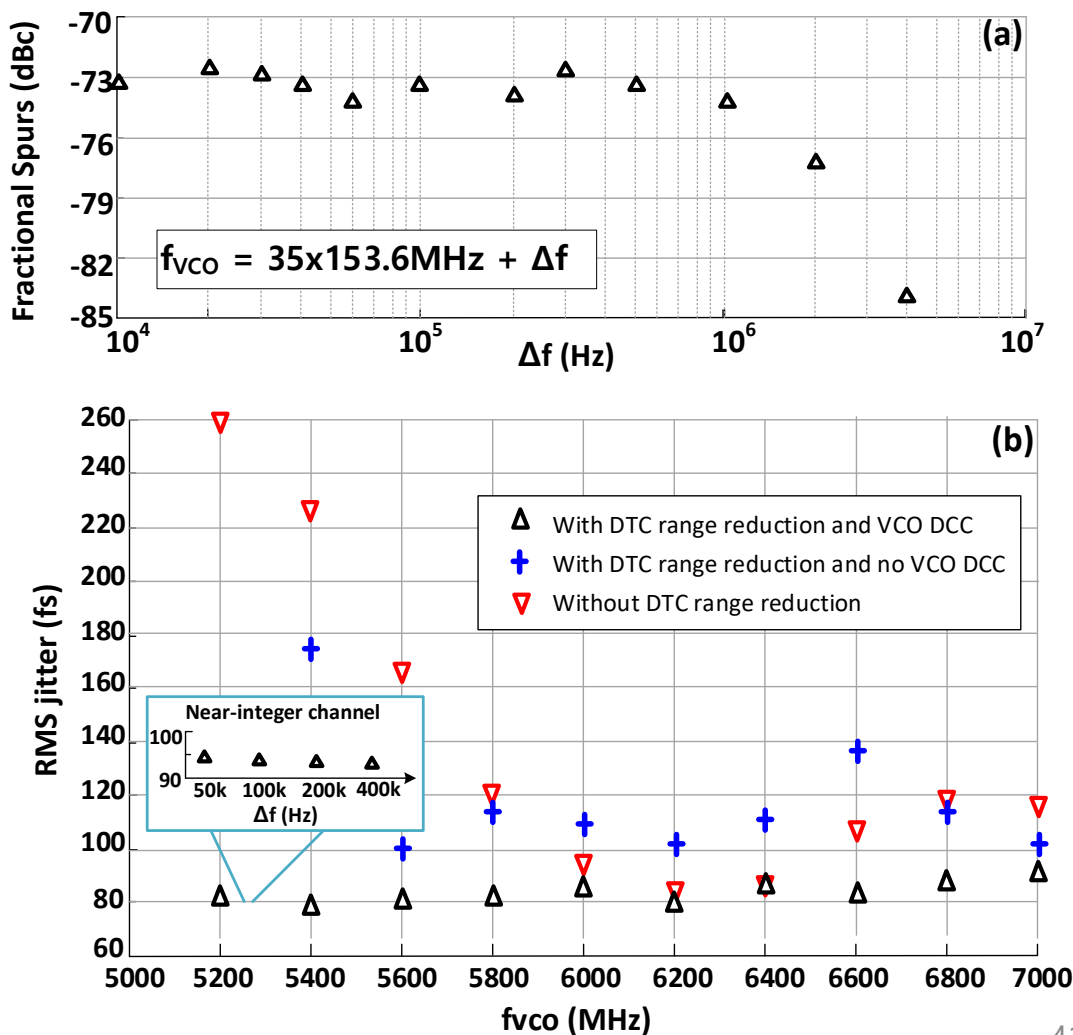


- All calibrations converge $< 30\mu s$ and track PVT
- Works robustly for both integer and fractional channels

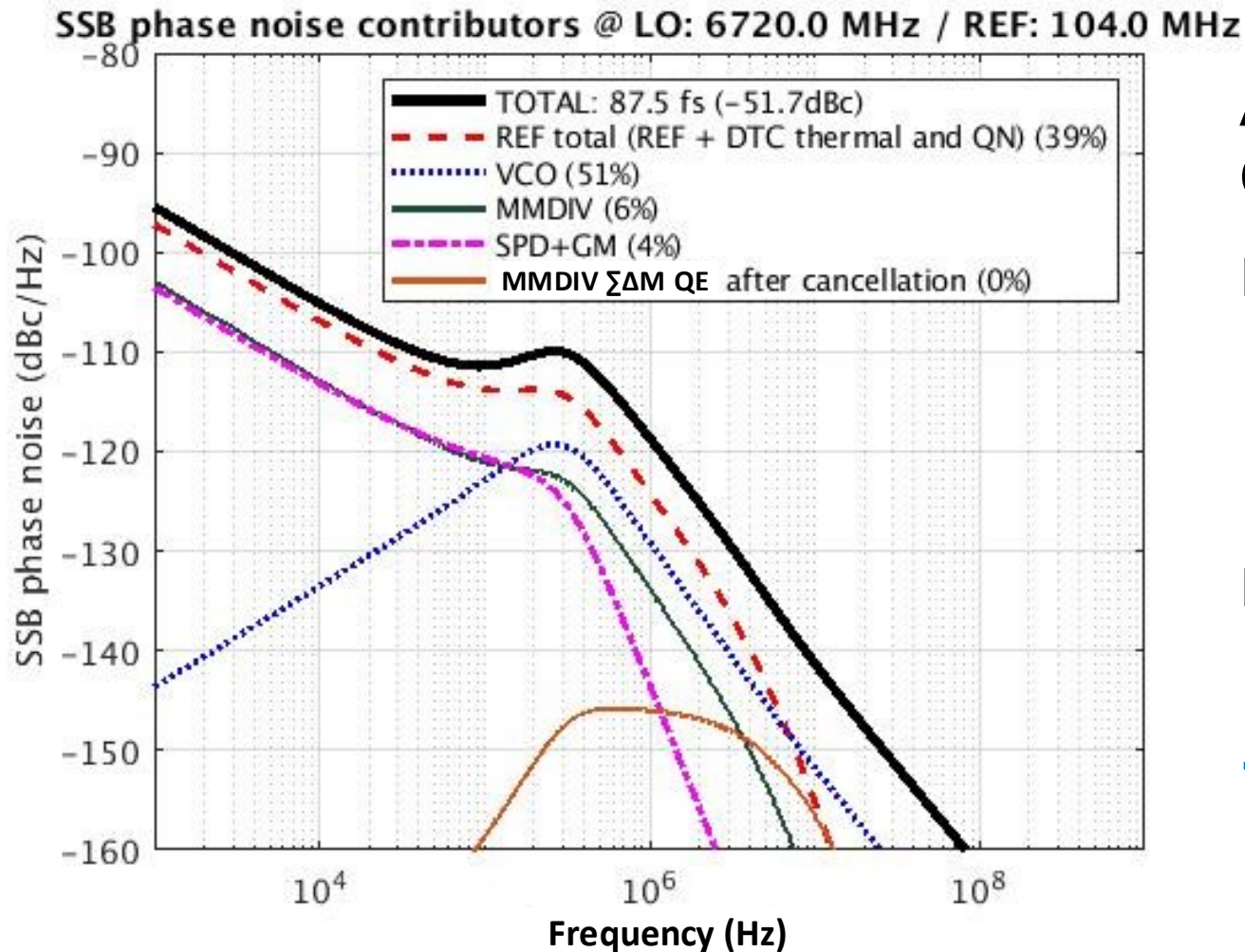
Measured Fractional-N Spurs and Jitter



[W. Wu ISSCC 2021]



PN Contributors in Low-Jitter DTC-Assisted PLL



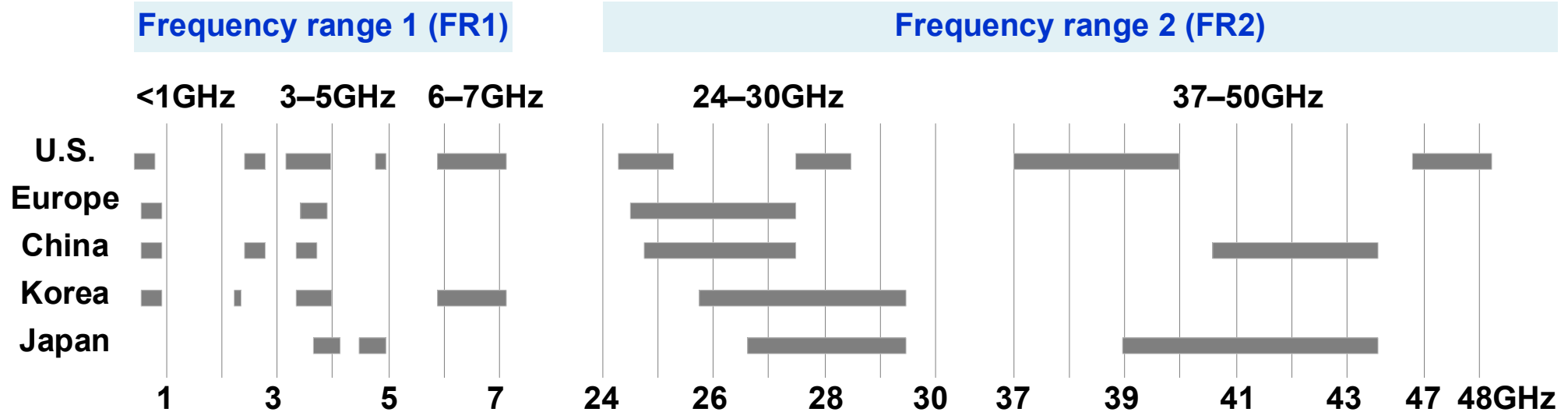
After suppress noise from PD, DSM QN, MMD →

- PLL IPN is dominated by
 - CKREF – external clock ref.
 - VCO/DCO
 - PLL BW is chosen to tradeoff the contribution of the two
- Common for any PLLs

Outline

- Fractional-N PLL Design Challenges
- PLL Architecture Review
- DTC-Assisted Phase Detector Design
- Digital Calibrations to Enhance PLL Performance
- **LO Chain Design Example for 5G NR**

5G New Radio Frequency Bands

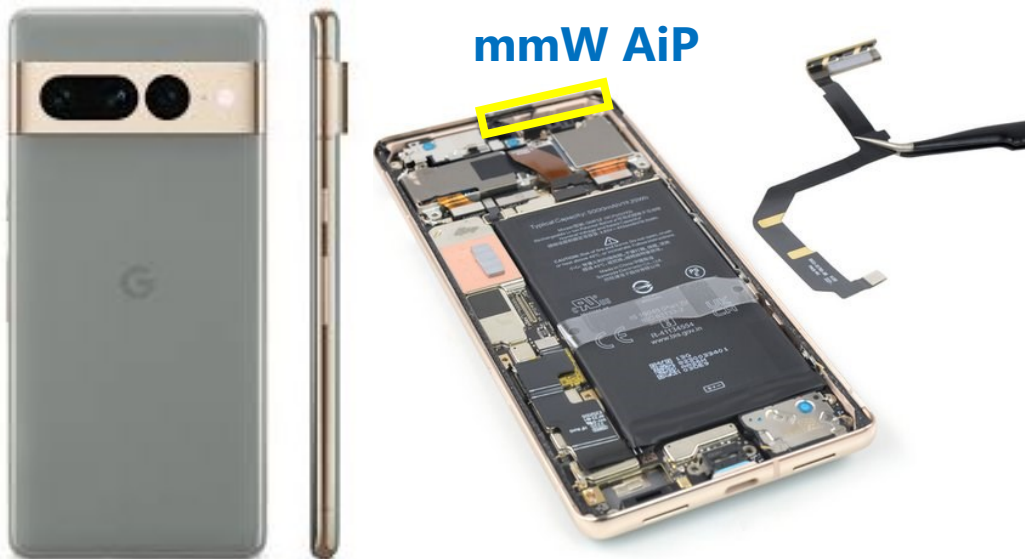


5G FR2 Band	Uplink/Downlink (GHz)	Channel bandwidth (MHz)
N257	TDD 26.5 – 29.5	50, 100, 200, 400
N258	TDD 24.25 – 27.5	50, 100, 200, 400
N259	TDD 39.5 – 43.5	50, 100, 200, 400
N260	TDD 37.0 – 40.0	50, 100, 200, 400
N261	TDD 27.5 – 28.35	50, 100, 200, 400

Smart Phones with 5G mmW Chipset

■ FR2 system

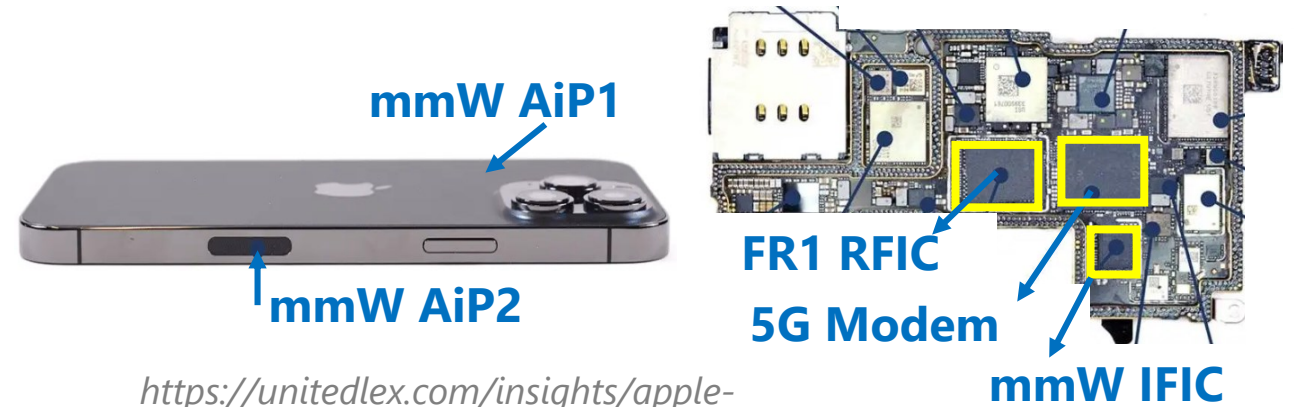
Modem + mmW IFIC + mmW AiP



<https://www.ifixit.com/Guide/Google+Pixel+7+Pro+5G+mmWave+Antenna+Replacement/154719>

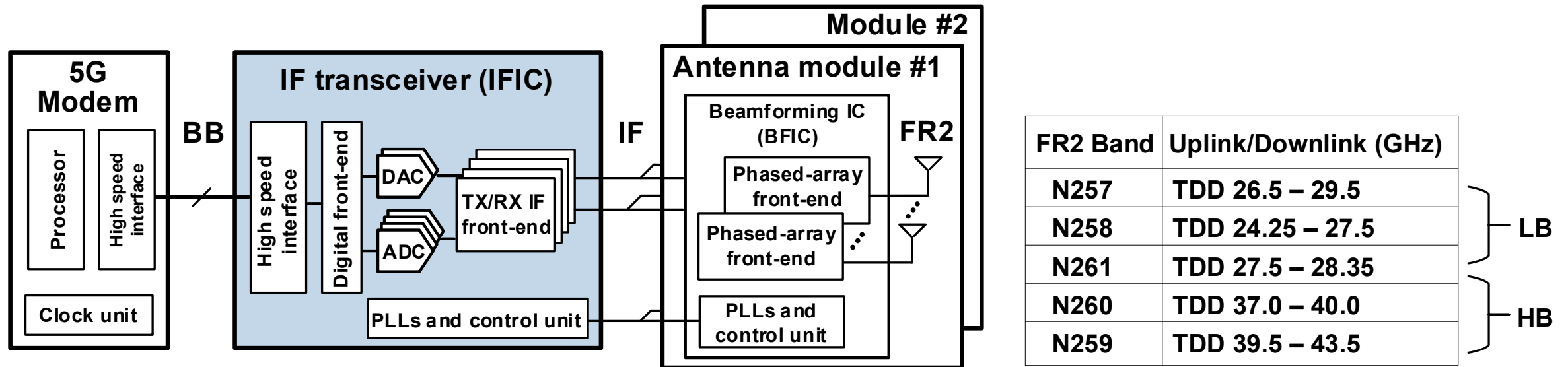


<https://www.techinsights.com/blog/muratasamsung-2nd-gen-mmwave-aip-discovered-samsung-galaxy-a53>



<https://unitedlex.com/insights/apple-iphone-13-pro-max-teardown-report/>

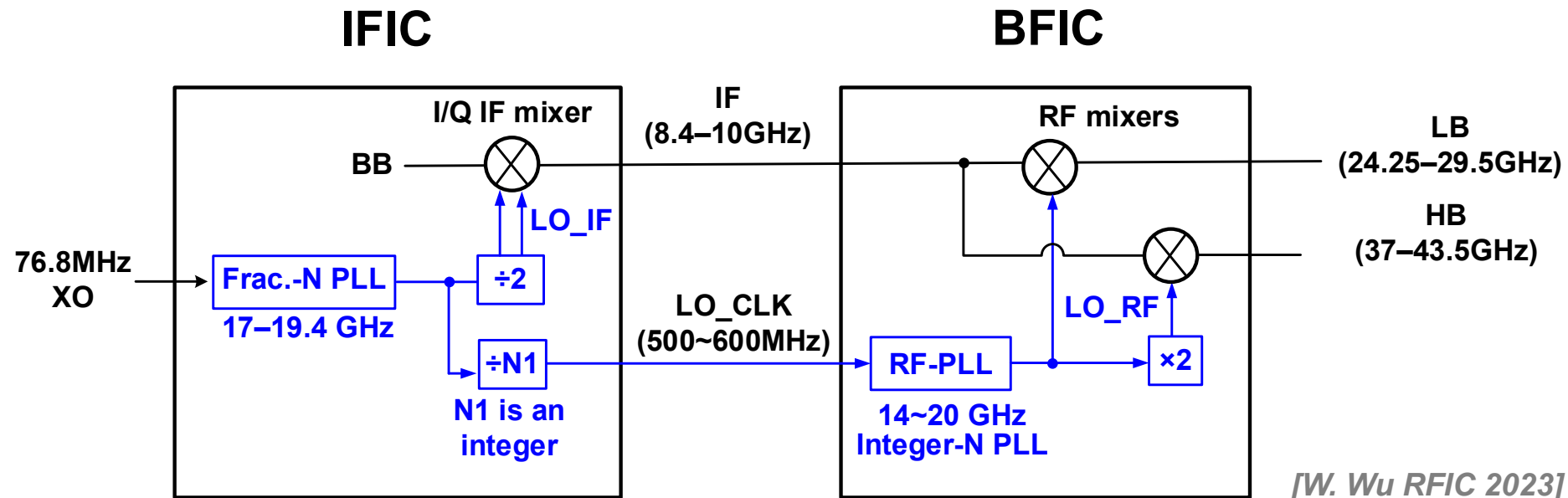
LO Design Challenges for 5G mmW



- mmW LO circuitry on **both IFIC and BFIC**
- Transceiver SNR is **limited by LO IPN**
- **Multi-band** support with **low power and low cost**
- **256-QAM** support demands **low jitter LO**

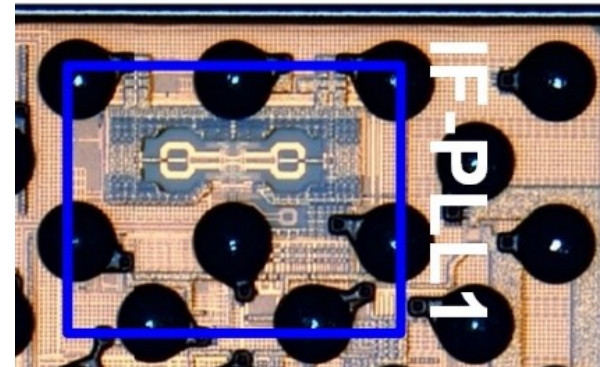
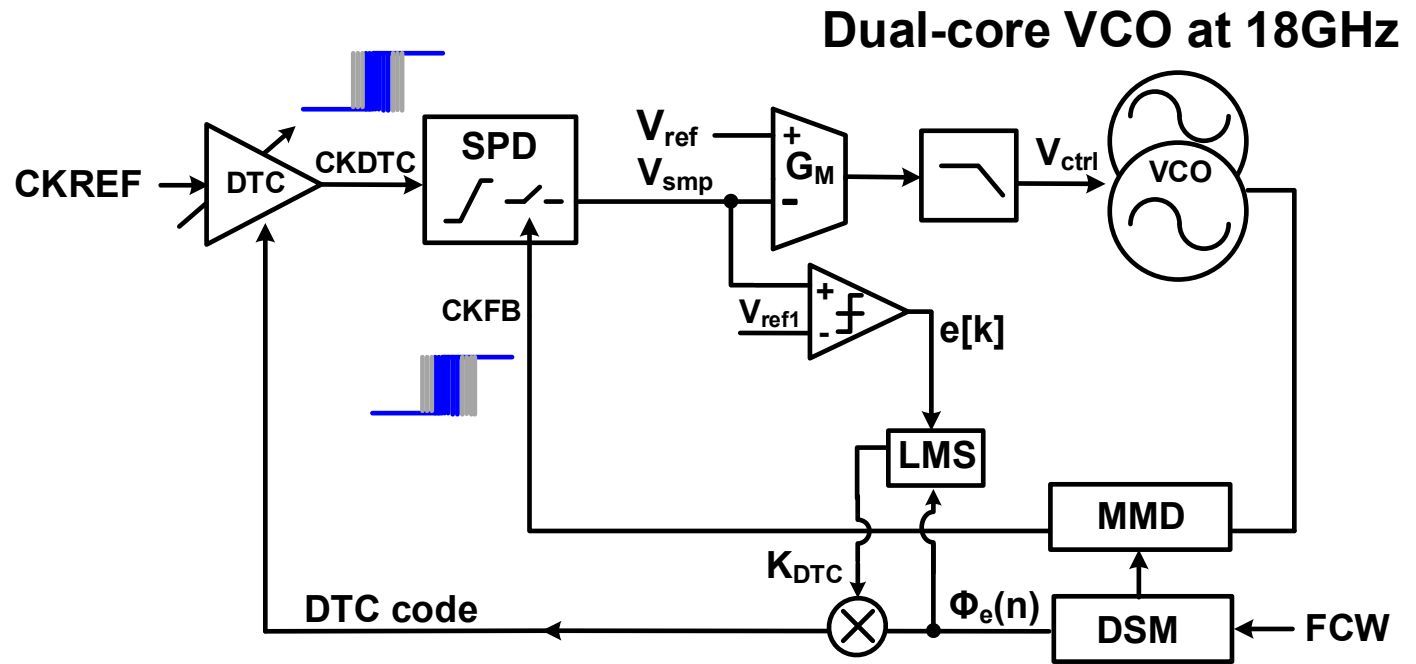
LO Topology Considerations

- IFIC generates LO_IF & reference clock (LO_CLK) for BFIC
- Low-jitter frac.-N PLL dominates LO chain IPN
- BFIC PLL simplifies to an integer-N of wide BW (e.g., SSPLL)
 - Low-power as VCO PN is relaxed
 - Compact area: one wideband VCO for both LB and HB



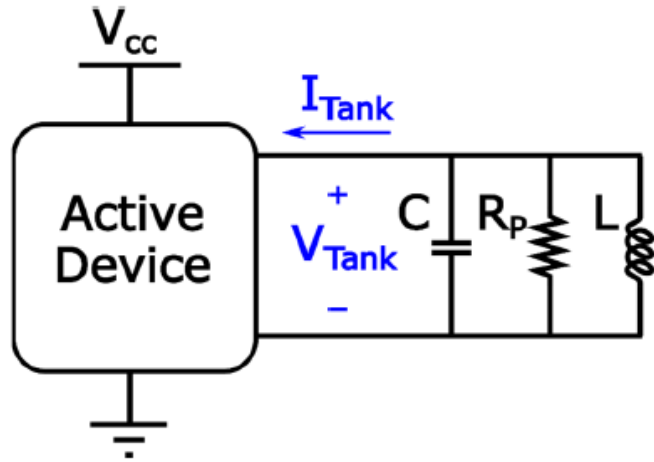
Low-Jitter Fractional-N PLL Directly at mmW

- DTC-based sampling PLL
→ low jitter
- VCO operates at 18 GHz
→ no multiplier, low power
- Dual-core VCO → low jitter



[W. Wu RFIC 2023]

Low PN LC Oscillator Design



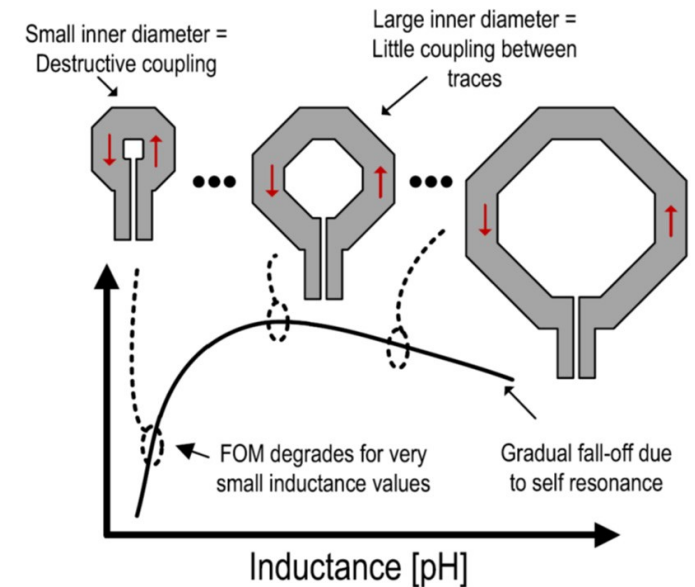
$$PN_{dB} = 10 \log_{10} \left[\left(\frac{\omega_0}{2Q\Delta\omega} \right)^2 \frac{2FkT}{P} \right] = 10 \log_{10} \left[\left(\frac{\omega_0}{\Delta\omega} \right)^2 \frac{FkT\omega_0}{V_{Tank}^2} \frac{L}{Q} \right]$$

$$\text{Resonator power } P = \frac{V_{Tank}^2}{2R_p} = \frac{V_{Tank}^2}{2\omega_0 L Q}$$

- V_{Tank} , F set by process
- Scaling L as long as $\frac{L}{Q}$ can be reduced to lower PN
- Beyond this limit \rightarrow use multi-core oscillator

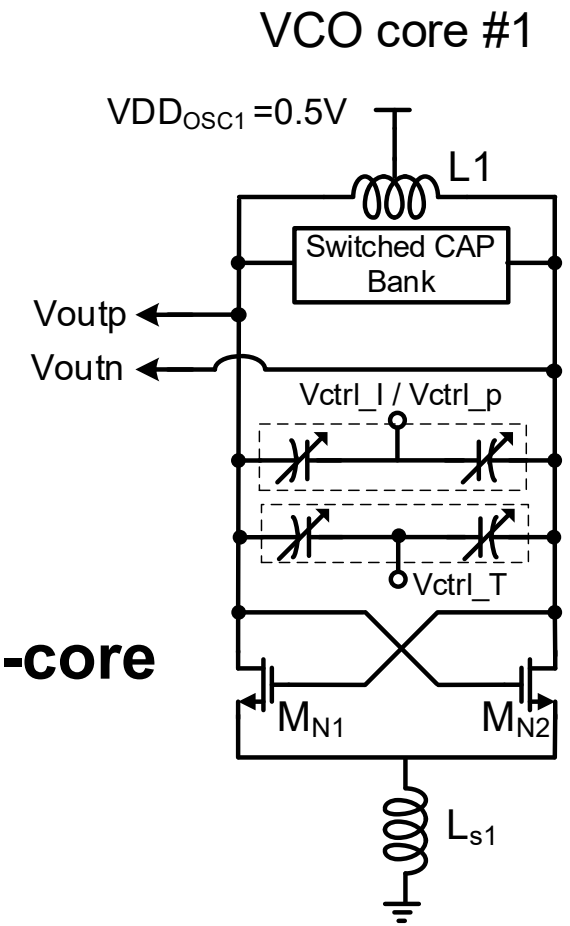
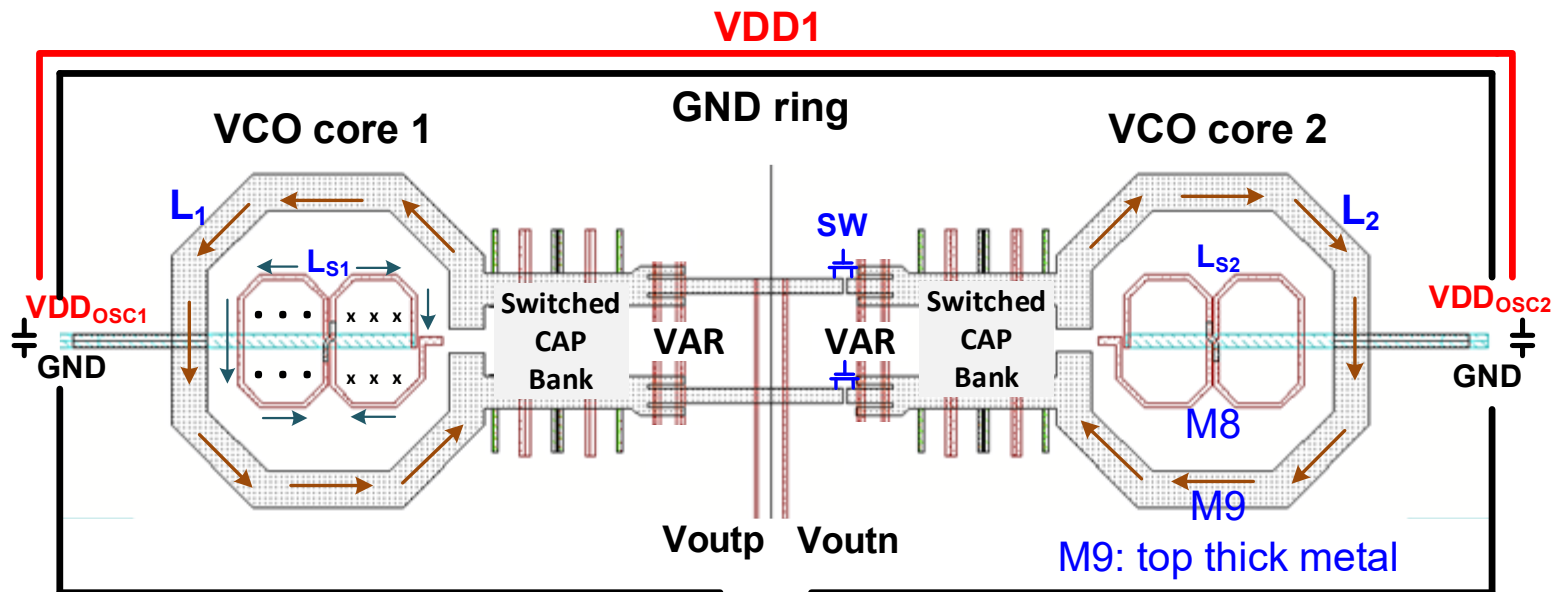
$$L_{eq} = L/N, C_{eq} = N \cdot C \rightarrow \text{same } \omega_0, \text{ same } Q$$

$$PN_{multi-core} = PN_0 - 10 \log_{10}(N)$$



[D. Murphy JSSC Nov 2018]

Switchable Dual-core VCO for Power, PN Tradeoff



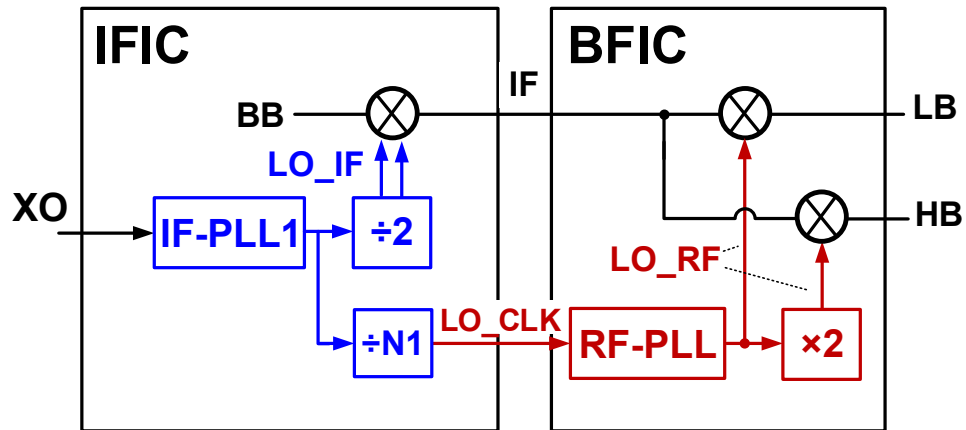
- Good EM isolation, symmetrical → same f_{vco} for 1- or 2-core
- Figure-8 tail L_s put inside main L to save area
- N=1: -120 dBc/Hz @1MHz measured at 6GHz
- N=2: -122.5 dBc/Hz

[W. Wu ISSCC 2021]

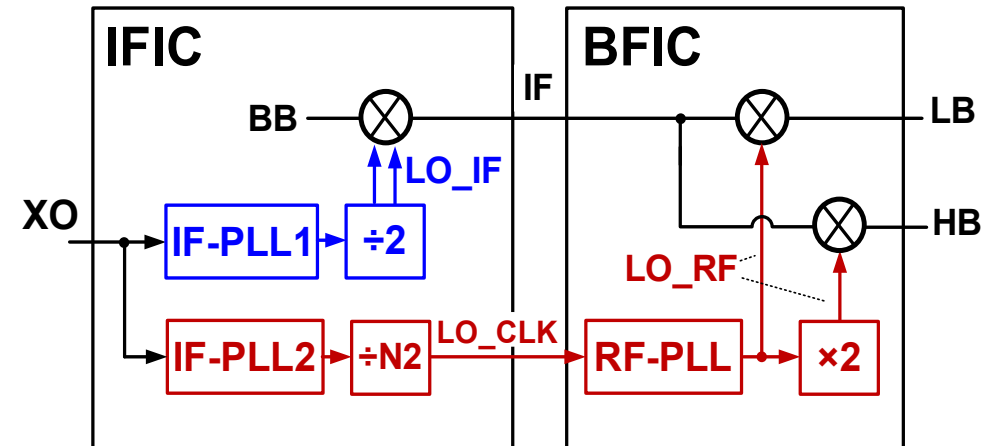
LO Configuration to Further Improve IPN

- 256-QAM requires rms jitter of ~ 100 fs
- Hard to further reduce rms jitter of IF-PLL \rightarrow use two IF-PLLs
- PN of LO_IF and LO_RF are mostly uncorrelated \rightarrow lower chain IPN

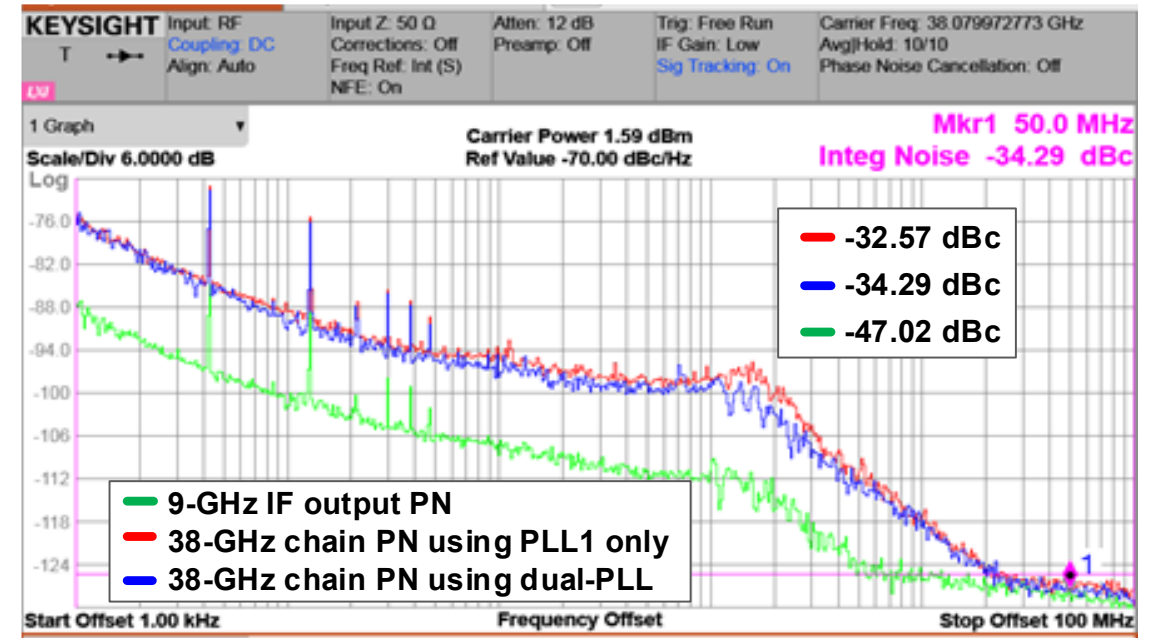
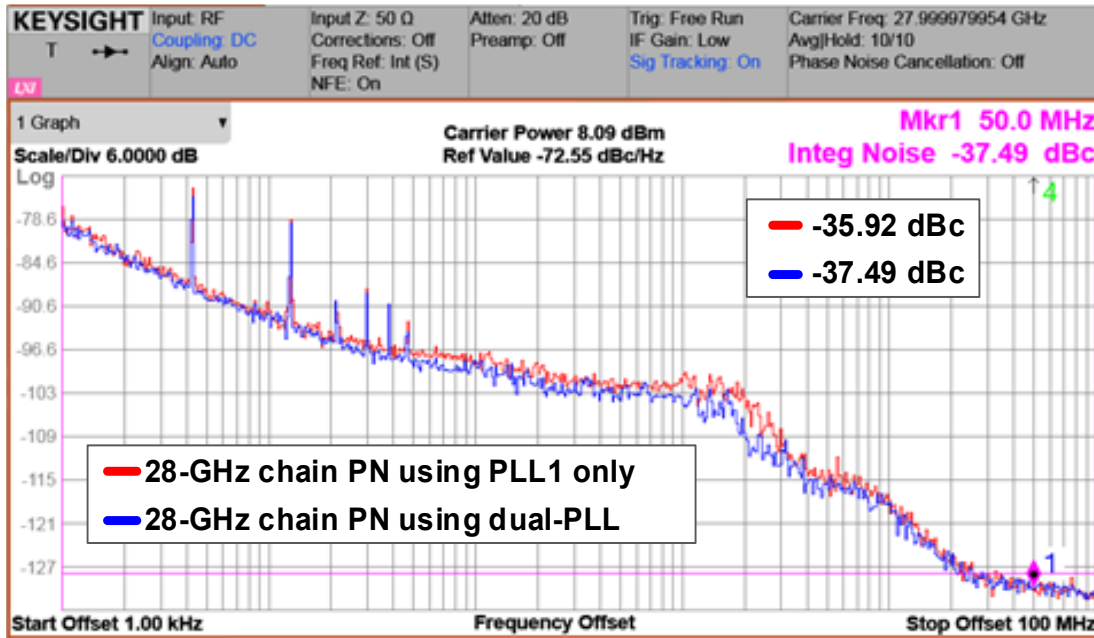
Low-power mode for 64-QAM/QPSK



Low-jitter mode for 256-QAM



Measured Chain IPN at 28 GHz and 38 GHz



[W. Wu RFIC 2023, Samsung]

- Dual-PLL results in ~ 1.6 dB lower chain IPN
- -37.49 dBc IPN at 28 GHz \rightarrow EVM floor of 1.34%
- -34.29 dBc IPN at 38 GHz \rightarrow 112 fs rms jitter, EVM floor of 1.9%

Summary

- Advanced wireless application requires **frac. N PLLs of $< 100 f_{s_{rms}}$**
- PLLs with **DTC-assisted PD** have demonstrates low jitter, high FoM
- **DTC cancels DSM QE** → eases PD design
- Various design techniques aim to **improve DTC linearity**
- **Intensive digital calibrations** enhance PLL performance
- **Multi-core VCO** breaks design limit of single core with same VCO FoM

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